

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[STMicroelectronics](#)

[STM6601AQ2BDM6F](#)

For any questions, you can email us directly:

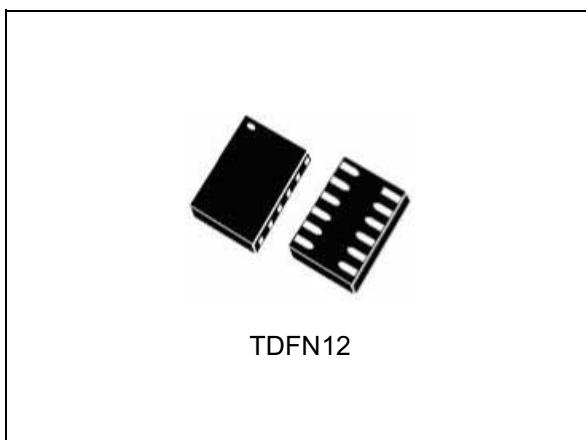
sales@integrated-circuit.com



STM6600, STM6601

Smart push-button on/off controller with Smart Reset™ and power-on lockout

Datasheet - production data



TDFN12

- Debounced \overline{PB} and \overline{SR} inputs
- \overline{PB} and \overline{SR} ESD inputs withstand voltage up to ± 15 kV (air discharge) ± 8 kV (contact discharge)
- Active high or active low enable output option (EN or \overline{EN}) provides control of MOSFET, DC-DC converter, regulator, etc.
- Secure startup, interrupt, Smart Reset™ or power-down driven by push-button
- Precise 1.5 V voltage reference with 1% accuracy
- Industrial operating temperature -40 to $+85$ °C
- Available in TDFN12 2 x 3 mm package

Features

- Operating voltage 1.6 V to 5.5 V
- Low standby current of 0.6 μ A
- Adjustable Smart Reset™ assertion delay time driven by external C_{SRD}
- Power-up duration determined primarily by push-button press (STM6600) or by fixed time period, t_{ON_BLANK} (STM6601)

Applications

- Portable devices
- Terminals
- Audio and video players
- Cell phones and smart phones
- PDAs, palmtops, organizers

Table 1. Device summary

Device	\overline{RST}	C_{SRD}	$\overline{PB} / \overline{SR}$	EN or \overline{EN}	\overline{INT}	Startup process
STM6600	open drain ⁽¹⁾	✓	✓	Push-pull	Open drain ⁽¹⁾	\overline{PB} must be held low until the $PS_{HOLD}^{(2)}$ confirmation
STM6601	open drain ⁽¹⁾	✓	✓	Push-pull	Open drain ⁽¹⁾	PB can be released before the $PS_{HOLD}^{(2)}$ confirmation

1. External pull-up resistor needs to be connected to open drain outputs.
2. For a successful startup, the PS_{HOLD} (power supply hold) needs to be pulled high within specific time, t_{ON_BLANK} .

Contents**STM6600, STM6601****Contents**

1	Description	5
2	Pin descriptions	9
3	Operation	12
4	Waveforms	14
5	Typical operating characteristics	28
6	Maximum ratings	38
7	DC and AC characteristics	39
8	Package mechanical data	42
9	Part numbering	46
10	Product selector	49
11	Revision history	51

List of tables

Table 1.	Device summary	1
Table 2.	Pin descriptions	7
Table 3.	Absolute maximum ratings	38
Table 4.	Operating and AC measurement conditions	39
Table 5.	DC and AC characteristics	39
Table 6.	TDFN12 (2 x 3 mm) package mechanical data	43
Table 7.	Carrier tape dimensions for TDFN12 (2 x 3 mm) package	45
Table 8.	STM6600 ordering information scheme	46
Table 9.	STM6601 ordering information scheme	48
Table 10.	STM6600 product selector	49
Table 11.	STM6601 product selector	50
Table 12.	Document revision history	51

List of figures

STM6600, STM6601

List of figures

Figure 1. Application hookup	5
Figure 2. Basic functionality (option with enable deassertion after long push)	6
Figure 3. Basic functionality (option with \overline{RST} assertion after long push)	6
Figure 4. Logic diagram	6
Figure 5. TDFN12 pin connections	7
Figure 6. Block diagram	8
Figure 7. Successful power-up on STM6600 (\overline{PB} released prior to t_{ON_BLANK} expiration)	14
Figure 8. Successful power-up on STM6600 (t_{ON_BLANK} expires prior to PB release)	15
Figure 9. Unsuccessful power-up on STM6600 (\overline{PB} released prior to t_{ON_BLANK})	16
Figure 10. Unsuccessful power-up on STM6600 (t_{ON_BLANK} expires prior to PB release)	17
Figure 11. Successful power-up on STM6601	18
Figure 12. Unsuccessful power-up on STM6601	19
Figure 13. Power-up on STM660x with voltage dropout	20
Figure 14. \overline{PB} interrupt	21
Figure 15. Long push, \overline{PB} pressed first	22
Figure 16. Long push, SR pressed first	22
Figure 17. Invalid long push	23
Figure 18. Long push (option with RST assertion)	24
Figure 19. Long push (option with enable deassertion)	25
Figure 20. Undervoltage detected for $<t_{SRD}$	26
Figure 21. Undervoltage detected for $>t_{SRD}$	26
Figure 22. \overline{PB}_{OUT} output waveform	27
Figure 23. Supply current vs. temperature, normal state	28
Figure 24. Supply current vs. temperature, standby state	28
Figure 25. Supply current vs. supply voltage, normal state	29
Figure 26. Supply current vs. supply voltage, standby state	29
Figure 27. Threshold vs. temperature, $V_{TH+} = 3.4$ V (typ.)	30
Figure 28. Threshold hysteresis vs. temperature, $V_{HYST} = 200$ mV (typ.)	30
Figure 29. Debounce period vs. supply voltage	31
Figure 30. C_{SRD} charging current vs. temperature, $V_{CC} = 3.6$ V	31
Figure 31. Output low voltage vs. output low current, $T_A = 25$ °C	32
Figure 32. Output high voltage vs. output high current, $T_A = 25$ °C	32
Figure 33. Output voltage vs. supply voltage, $I_{OUT} = 1$ mA, $T_A = 25$ °C	33
Figure 34. Input voltage vs. temperature	33
Figure 35. Reference output voltage vs. temperature, $V_{CC} = 2.0$ V	34
Figure 36. Reference output voltage vs. load current, $V_{CC} = 2.0$ V, $T_A = 25$ °C	34
Figure 37. Reference output voltage vs. supply voltage, $T_A = 25$ °C	35
Figure 38. Reference startup, $I_{REF} = 15$ μ F, $T_A = 25$ °C	35
Figure 39. Reference response to steps on supply voltage, $I_{REF} = 15$ μ A, $T_A = 25$ °C	36
Figure 40. Reference response to steps in load current, $V_{CC} = 3.6$ V, $T_A = 25$ °C	37
Figure 41. TDFN12 (2 x 3 mm) package outline	43
Figure 42. TDFN12 (2 x 3 mm) recommended footprint	44
Figure 43. Carrier tape for TDFN12 (2 x 3 mm) package	45

STM6600, STM6601

Description

1 Description

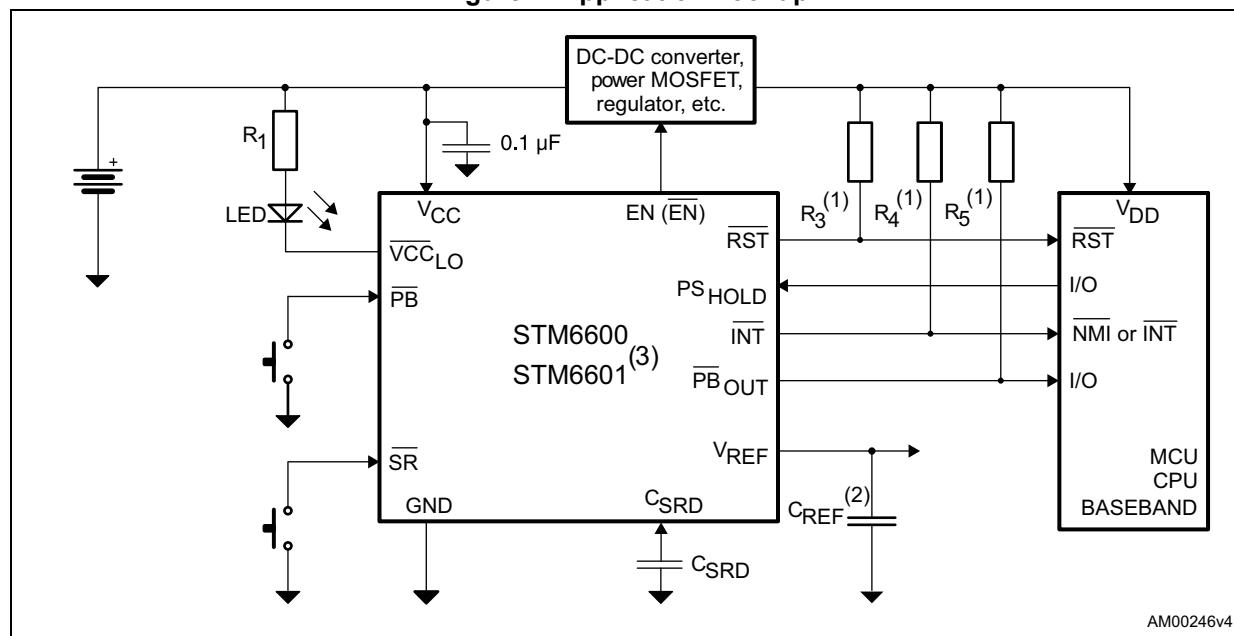
The STM6600-01 devices monitor the state of connected push-button(s) as well as sufficient supply voltage. An enable output controls power for the application through the MOSFET transistor, DC-DC converter, regulator, etc. If the supply voltage is above a precise voltage threshold, the enable output can be asserted by a simple press of the button. Factory-selectable supply voltage thresholds are determined by highly accurate and temperature-compensated references. An interrupt is asserted by pressing the push-button during normal operation and can be used to request a system power-down. The interrupt is also asserted if undervoltage is detected. By a long push of one button (PB) or two buttons (PB and SR) either a reset is asserted or power for the application is disabled depending on the option used.

The device also offers additional features such as precise 1.5 V voltage reference with very tight accuracy of 1%, separate output indicating undervoltage detection and separate output for distinguishing between interrupt by push-button or undervoltage.

The device consumes very low current of 6 μ A during normal operation and only 0.6 μ A current during standby.

The STM6600-01 is available in the TDFN12 package and is offered in several options among features such as selectable threshold, hysteresis, timeouts, output types, etc.

Figure 1. Application hookup

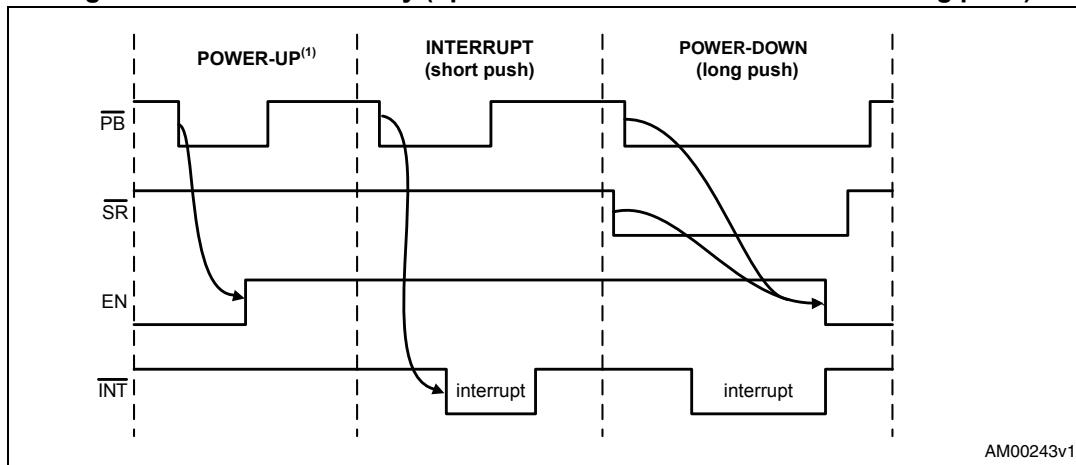


1. A resistor is required for open drain output type only. A 10 k Ω pull-up is sufficient in most applications.
2. Capacitor C_{REF} is mandatory on V_{REF} output (even if V_{REF} is not used). Capacitor value of 1 μ F is recommended.
3. For the STM6601 the processor has to confirm the proper power-on during the fixed time period, t_{ON_BLANK} . This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.

Description

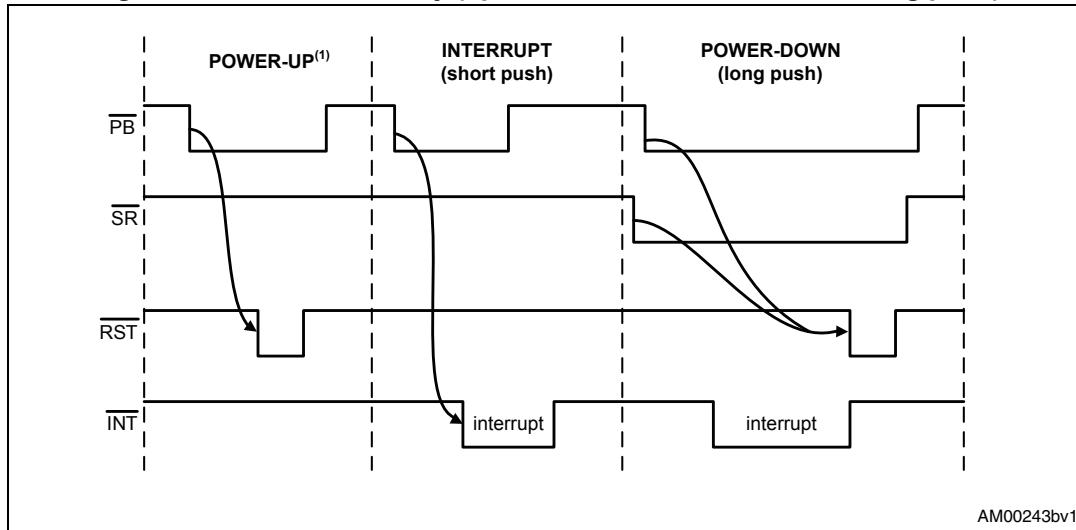
STM6600, STM6601

Figure 2. Basic functionality (option with enable deassertion after long push)



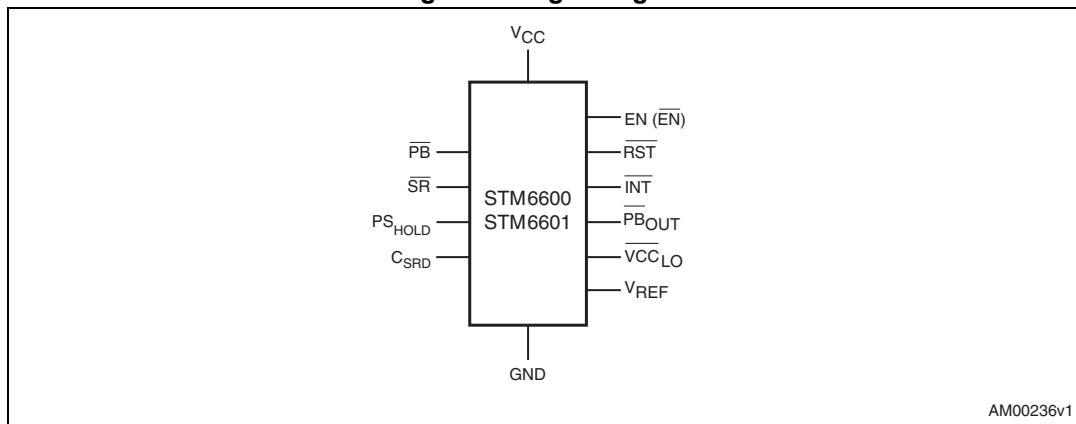
1. For power-up the battery voltage has to be above V_{TH+} threshold.

Figure 3. Basic functionality (option with RST assertion after long push)



1. For power-up the battery voltage has to be above V_{TH+} threshold.

Figure 4. Logic diagram



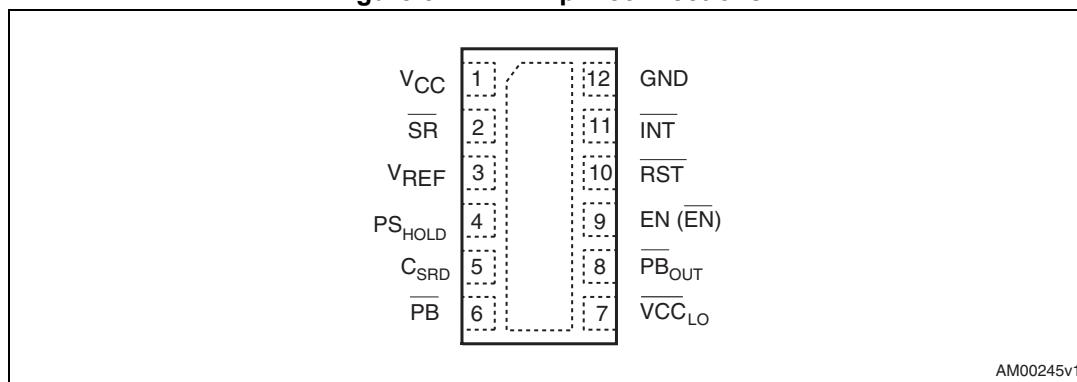
STM6600, STM6601

Description

Table 2. Pin descriptions

Pin number	Symbol	Function
1	V_{CC}	Power supply input
2	\overline{SR}	Smart Reset™ button input
3	V_{REF}	Precise 1.5 V voltage reference
4	PS_{HOLD}	PS_{HOLD} input
5	C_{SRD}	Adjustable Smart Reset™ delay time input
6	\overline{PB}	Push-button input
7	\overline{VCC}_{LO}	Output for high threshold comparator output (V_{TH+})
8	\overline{PB}_{OUT}	Status of \overline{PB} push-button input
9	EN or \overline{EN}	Enable output
10	\overline{RST}	Reset output
11	\overline{INT}	Interrupt output
12	GND	Ground

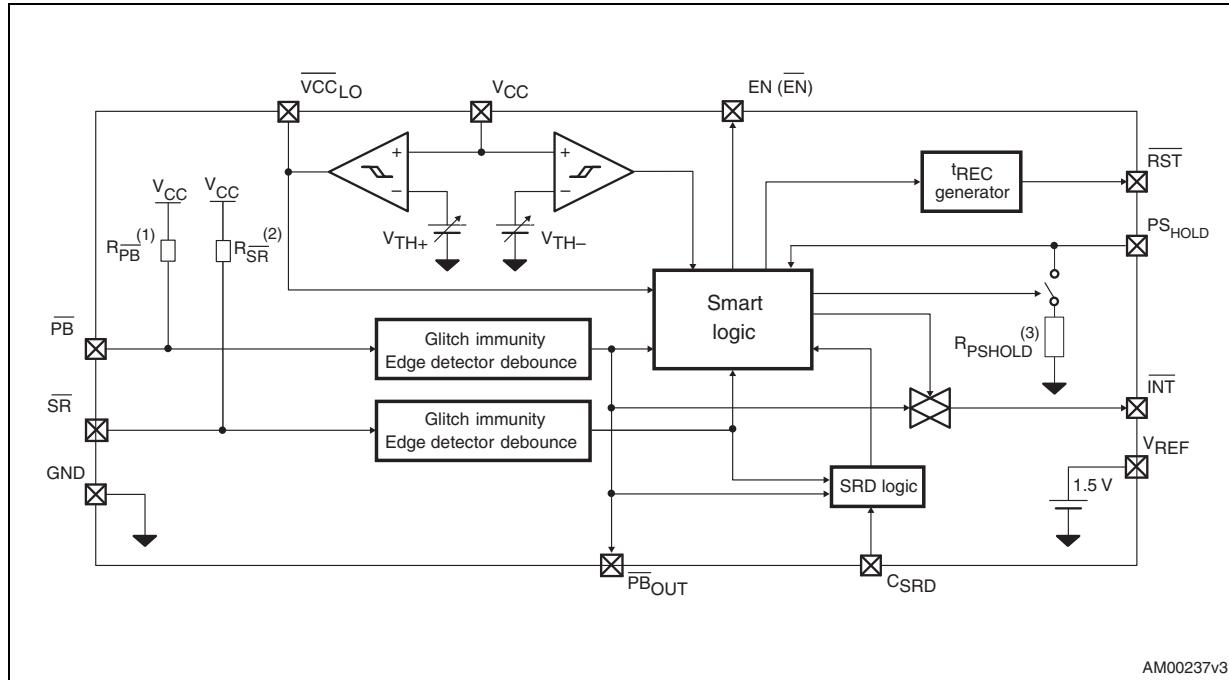
Figure 5. TDFN12 pin connections



Description

STM6600, STM6601

Figure 6. Block diagram



AM00237v3

1. Internal pull-up resistor connected to \overline{PB} input (see [Table 5](#) for precise specifications).
2. Optional internal pull-up resistor connected to \overline{SR} input (see [Table 5](#) for precise specifications and [Table 10](#) for detailed device options).
3. Internal pull-down resistor is connected to PS_{HOLD} input only during startup (see [Figure 7, 8, 9, 10, 11, 12, 13](#), and [18](#)).

STM6600, STM6601**Pin descriptions**

2 Pin descriptions

V_{CC} - power supply input

V_{CC} is monitored during startup and normal operation for sufficient voltage level. Decouple the V_{CC} pin from ground by placing a 0.1 μ F capacitor as close to the device as possible.

SR - Smart Reset™ button input

This input is equipped with voltage detector with a factory-trimmed threshold and has ± 8 kV HBM ESD protection.

Both \overline{PB} and \overline{SR} buttons have to be pressed and held for t_{SRD} period so the long push is recognized and the reset is asserted (or the enable output is deasserted depending on the option) - see [Figure 15, 16, and 17](#).

Active low \overline{SR} input is usually connected to GND through the momentary push-button (see [Figure 1](#)) and it has an optional 100 k Ω pull-up resistor. It is also possible to drive this input using an external device with either open drain (recommended) or push-pull output. Open drain output can be connected in parallel with push-button or other open drain outputs, which is not possible with push-pull output. \overline{SR} input is monitored for falling edge after power-up and must not be grounded permanently.

V_{REF} - external precise 1.5 V voltage reference

This 1.5 V voltage reference is specified with very tight accuracy of 1% (see [Table 5](#)). It has proper output voltage as soon as the reset output is deasserted (i.e. after t_{REC} expires) and it is disabled when the device enters standby mode. A mandatory capacitor needs to be connected to V_{REF} output (even if V_{REF} is not used). Capacitor value of 1 μ F is recommended.

PS_{HOLD} input

This input is equipped with a voltage detector with a factory-trimmed threshold. It is used to confirm correct power-up of the device (if EN or \overline{EN} is not asserted) or to initiate a shutdown (if EN or \overline{EN} is asserted).

Forcing PS_{HOLD} high during power-up confirms the proper start of the application and keeps enable output asserted. Because most processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS_{HOLD} input during startup (see [Figure 7, 8, 9, 10, 11, 12, 13, and 18](#)).

Forcing the PS_{HOLD} signal low during normal operation deasserts the enable output (see [Figure 14](#)). Input voltage on this pin is compared to an accurate voltage reference.

C_{SRD} - Smart Reset™ delay time input

A capacitor to ground determines the additional time (t_{SRD}) that \overline{PB} with \overline{SR} must be pressed and held before a long push is recognized. The connected C_{SRD} capacitor is charged with I_{SRD} current. Additional Smart Reset™ delay time t_{SRD} ends when voltage on the C_{SRD} capacitor reaches the V_{SRD} voltage threshold. It is recommended to use a low ESR capacitor (e.g. ceramic). If the capacitor is not used, leave the C_{SRD} pin open. If no capacitor is connected, there is no t_{SRD} and a long push is recognized right after t_{INT_Min} expires (see [Figure 18 and 19](#)).

Pin descriptions**STM6600, STM6601****PB - power ON switch**

This input is equipped with a voltage detector with a factory-trimmed threshold and has ± 8 kV HBM ESD protection.

When the \overline{PB} button is pressed and held, the battery voltage is detected and EN (or \overline{EN}) is asserted if the battery voltage is above the threshold V_{TH+} during the whole $t_{DEBOUNCE}$ period (see [Figure 13](#)).

A short push of the push-button during normal operation can initiate an interrupt through debounced INT output (see [Figure 14](#)) and a long push of PB and SR simultaneously can either assert reset output RST (see [Figure 18](#)) or deassert the EN or \overline{EN} output (see [Figure 19](#)) based on the option used.

Note: A switch to GND must be connected to this input (e.g. mechanical push-button, open drain output of external circuitry, etc.), see [Figure 1](#). This ensures a proper startup signal on PB (i.e. a transition from full V_{CC} below specified V_{IL}). \overline{PB} input has an internal 100 k Ω pull-up resistor connected.

 \overline{VCC}_{LO} - high threshold detection output

During power-up, \overline{VCC}_{LO} is low when V_{CC} supply voltage is below the V_{TH+} threshold. After successful power-up (i.e. during normal operation) \overline{VCC}_{LO} is low anytime undervoltage is detected (see [Figure 13](#)).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

\overline{VCC}_{LO} is floating when STM660x is in standby mode.

 \overline{PB}_{OUT} - \overline{PB} input state

If the push-button \overline{PB} is pressed, the pin stays low during the $t_{DEBOUNCE}$ time period. If \overline{PB} is asserted for the entire $t_{DEBOUNCE}$ period, \overline{PB}_{OUT} will then stay low for at least t_{INT_Min} . If \overline{PB} is asserted after t_{INT_Min} expires, \overline{PB}_{OUT} will return high as soon as \overline{PB} is deasserted (see [Figure 22](#)). \overline{PB}_{OUT} ignores PB assertion during an undervoltage condition. At startup on the STM6601 \overline{PB}_{OUT} will respond only to the first PB assertion and any other assertion will be ignored until t_{ON_BLANK} expires. This output is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

STM6600, STM6601

Pin descriptions

EN or $\overline{\text{EN}}$ - enable output

This output is intended to enable system power (see [Figure 1](#)). EN is asserted **high** after a valid turn-on event has been detected and confirmed (i.e. push-button has been pressed and held for t_{DEBOUNCE} or more and $V_{\text{CC}} > V_{\text{TH+}}$ voltage level has been detected - see [Figure 13](#)). EN is released **low** if any of the conditions below occur:

- the push-button is released before PS_{HOLD} is driven high (valid for STM6600, see [Figure 9](#)) or $t_{\text{ON_BLANK}}$ expires before PS_{HOLD} is driven high during startup (valid for both STM6600 and STM6601, see [Figure 10](#) and [12](#)).
- PS_{HOLD} is driven low during normal operation (see [Figure 14](#)).
- an undervoltage condition is detected for more than $t_{\text{SRD}} + t_{\overline{\text{INT}}_{\text{Min}}} + t_{\text{DEBOUNCE}}$ (see [Figure 21](#)).
- a long push of the buttons is detected (only for the device with option “EN deasserted by long push” - see [Figure 19](#)) or PS_{HOLD} is not driven high during $t_{\text{ON_BLANK}}$ after a long push of the buttons (only for the device with option “ $\overline{\text{RST}}$ asserted by long push” - see [Figure 18](#)).

Described logic levels are inverted in case of $\overline{\text{EN}}$ output. Output type is push-pull by default.

$\overline{\text{RST}}$ - reset output

This output pulls low for t_{REC} :

- during startup. $\overline{\text{PB}}$ has been pressed (falling edge on the $\overline{\text{PB}}$ detected) and held for at least t_{DEBOUNCE} and $V_{\text{CC}} > V_{\text{TH+}}$ (see [Figure 7, 8, 9, 10, 11, 12](#) and [13](#) for more details).
- after long push detection (valid only for the device with option “ $\overline{\text{RST}}$ asserted by long push”). $\overline{\text{PB}}$ has been pressed (falling edge on the $\overline{\text{PB}}$ detected) and held for more than $t_{\text{DEBOUNCE}} + t_{\text{SRD}}$ (additional Smart Reset™ delay time can be adjusted by the external capacitor C_{SRD}) - see [Figure 18](#).

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

$\overline{\text{INT}}$ - interrupt output

While the system is under normal operation (PS_{HOLD} is driven high, power for application is asserted), the INT is driven **low** if:

- V_{CC} falls below $V_{\text{TH-}}$ threshold (i.e. undervoltage is detected - see [Figure 20](#) and [21](#)).
- the falling edge on the $\overline{\text{PB}}$ is detected and the push-button is held for t_{DEBOUNCE} or more. $\overline{\text{INT}}$ is driven low after t_{DEBOUNCE} and stays low as long as $\overline{\text{PB}}$ is held. The INT signal is held high during power-up.

The state of the $\overline{\text{PB}_{\text{OUT}}}$ output can be used to determine if the interrupt was caused by either the assertion of the $\overline{\text{PB}}$ input, or was due to the detection of an undervoltage condition on V_{CC} .

$\overline{\text{INT}}$ output is asserted low for at least $t_{\overline{\text{INT}}_{\text{Min}}}$.

Output type is active low and open drain by default. Open drain output type requires a pull-up resistor. A 10 k Ω is sufficient in most applications.

GND - ground

Operation**STM6600, STM6601**

3 Operation

The STM6600-STM6601 simplified smart push-button on/off controller with Smart Reset™ and power-on lockout enables and disables power for the application depending on push-button states, signals from the processor, and battery voltage.

Power-on

Because most of the processors have outputs in high-Z state before initialization, an internal pull-down resistor is connected to PS_{HOLD} input during startup (see [Figure 7, 8, 9, 10, 11, 12, 13](#), and [18](#)).

To power up the device the push-button \overline{PB} has to be pressed for at least $t_{DEBOUNCE}$ and V_{CC} has to be above V_{TH+} for the whole $t_{DEBOUNCE}$ period. If the battery voltage drops below V_{TH+} during the $t_{DEBOUNCE}$, the counter is reset and starts to count again when $V_{CC} > V_{TH+}$ (see [Figure 13](#)). After $t_{DEBOUNCE}$ the enable signal is asserted (EN goes high, \overline{EN} goes low), reset output \overline{RST} is asserted for t_{REC} and then the startup routine is performed by the processor. During initialization, the processor sets the PS_{HOLD} signal high.

On the STM6600 the PS_{HOLD} signal has to be set high prior to push-button release and t_{ON_BLANK} expiration, otherwise the enable signal is deasserted (EN goes low, \overline{EN} goes high) - see [Figure 7, 8, 9, and 10](#). The time up to push-button release represents the maximum time allowed for the system to power up and initialize the circuits driving the PS_{HOLD} input. If the PS_{HOLD} signal is low at push-button release, the enable output is deasserted immediately, thus turning off the system power. If t_{ON_BLANK} expires prior to push-button release, the PS_{HOLD} state is checked at its expiration. This safety feature disables the power and prevents discharging the battery if the push-button is stuck or it is held for an unreasonable period of time and the application is not responding (see [Figure 8 and 10](#)). \overline{PB} status, INT status and V_{CC} undervoltage detection are not monitored until power-up is completed.

On the STM6601 the PS_{HOLD} signal has to be set high before t_{ON_BLANK} expires, otherwise the enable signal is deasserted - see [Figure 11 and 12](#). In this case the t_{ON_BLANK} period is the maximum time allowed for the power switch and processor to perform the proper power-on. If the PS_{HOLD} signal is low at the end of the blanking period, the enable output is released immediately, thus turning off the system power. PB status, INT status and V_{CC} undervoltage detection are not monitored during the entire t_{ON_BLANK} period. This failsafe feature prevents the user from turning on the system when there is a faulty power switch or an unresponsive microprocessor.

Push-button interrupt

If the device works under normal operation (i.e. PS_{HOLD} is high) and the push-button \overline{PB} is pressed for more than $t_{DEBOUNCE}$, a negative pulse with minimum t_{INT_Min} width is generated on the INT output. By connecting INT to the processor interrupt input (INT or NMI) a safeguard routine can be performed and the power can be shut down by setting PS_{HOLD} low - see [Figure 14](#).

Forced power-down mode

The PS_{HOLD} output can be forced low anytime during normal operation by the processor and can deassert the enable signal - see [Figure 14](#).

STM6600, STM6601**Operation****Undervoltage detection**

If V_{CC} voltage drops below V_{TH-} voltage threshold during normal operation, the \overline{INT} output is driven low (see [Figure 20](#) and [Figure 21](#)).

If an undervoltage condition is detected for $t_{DEBOUNCE} + t_{\overline{INT_Min}} + t_{SRD}$, the enable output is deasserted (see [Figure 21](#)).

Hardware reset or power-down while system not responding

If the system is not responding and the system hangs, the \overline{PB} and \overline{SR} push-buttons can be pressed simultaneously longer than $t_{DEBOUNCE} + t_{\overline{INT_Min}} + t_{SRD}$, and then

- a) either the reset output RST is asserted for t_{REC} and the processor is reset (valid only for the device with option “ RST asserted by long push”) – see [Figure 18](#)
- b) or the power is disabled by EN or \overline{EN} signal (valid only for the device with option “ EN deasserted by long push”) – see [Figure 19](#)

The t_{SRD} is set by the external capacitor connected to the C_{SRD} pin. \overline{SR} input is monitored for falling edge after power-up and must not be grounded permanently.

Standby

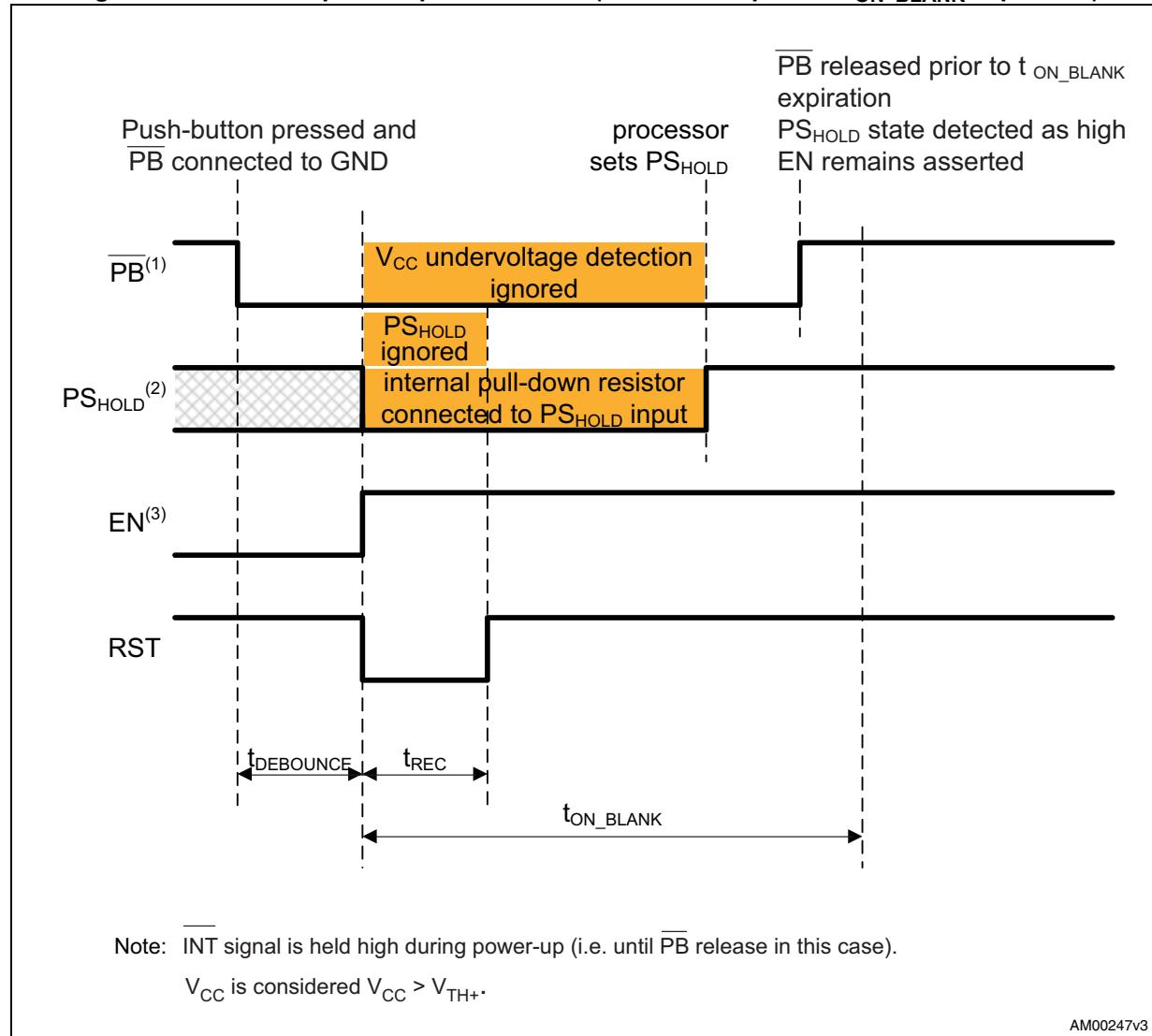
If the enable output is deasserted (i.e. EN is low or \overline{EN} is high), the STM660x device enters standby mode with low current consumption (see [Table 5](#)). In standby mode PB input is only monitored for the falling edge. The external 1.5 V voltage reference is also disabled in standby mode.

Waveforms

STM6600, STM6601

4 Waveforms

Figure 7. Successful power-up on STM6600 (\overline{PB} released prior to t_{ON_BLANK} expiration)

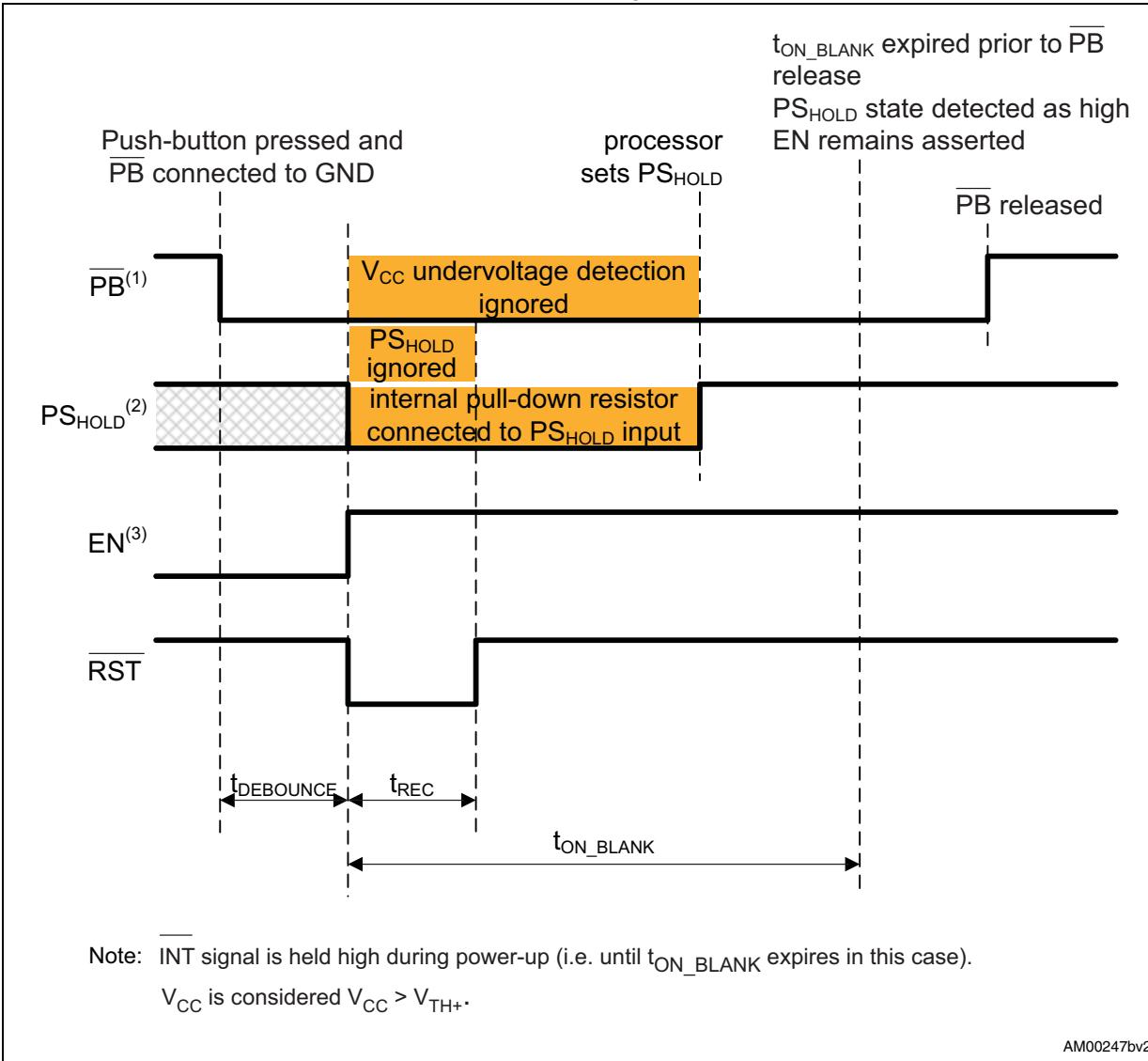


1. \overline{PB} detection on falling and rising edges.
2. Internal pull-down resistor $300\text{ k}\Omega$ is connected to PS_{HOLD} input during power-up.
3. EN signal is high even after \overline{PB} release, because processor sets PS_{HOLD} signal high before \overline{PB} is released.

STM6600, STM6601

Waveforms

Figure 8. Successful power-up on STM6600 (t_{ON_BLANK} expires prior to \overline{PB} release)

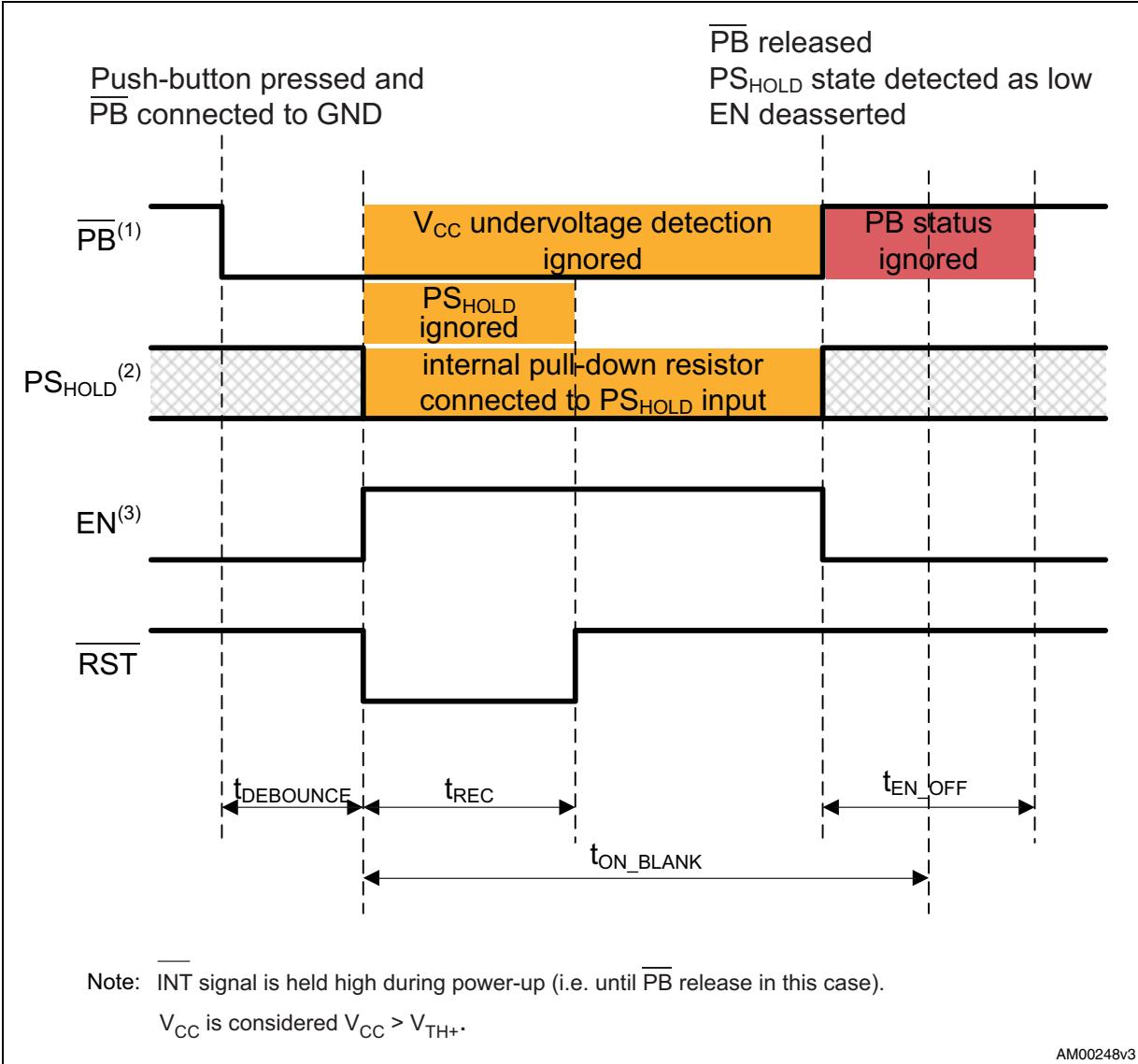


1. \overline{PB} detection on falling and rising edges.
2. Internal pull-down resistor $300\text{ k}\Omega$ is connected to PS_{HOLD} input during power-up.
3. t_{ON_BLANK} expires prior to \overline{PB} release so PS_{HOLD} is checked at its expiration.

Waveforms

STM6600, STM6601

Figure 9. Unsuccessful power-up on STM6600 ($\overline{\text{PB}}$ released prior to $t_{\text{ON_BLANK}}$)

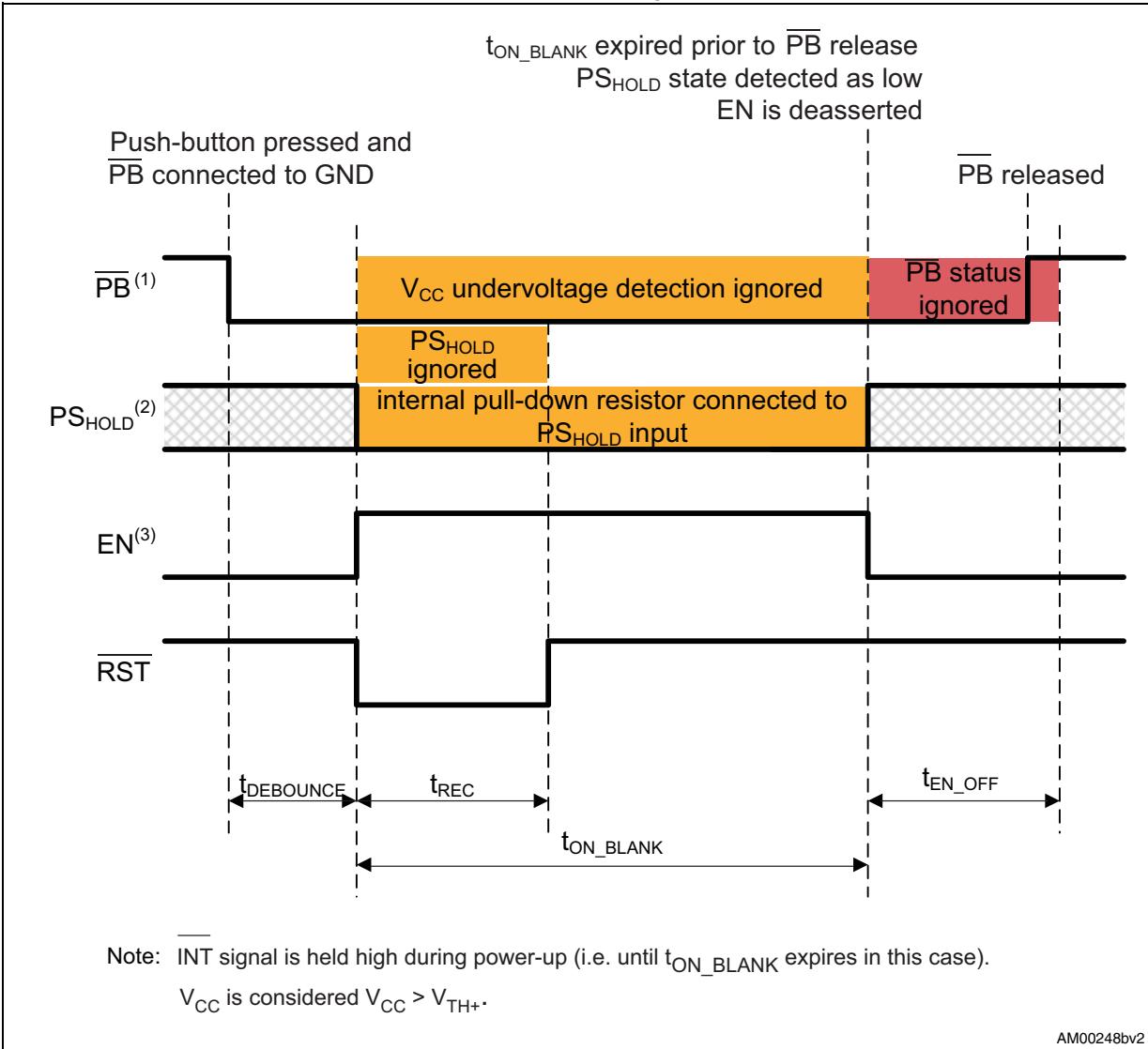


1. $\overline{\text{PB}}$ detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. EN signal goes low with $\overline{\text{PB}}$ release, because processor did not force PS_{HOLD} signal high.

STM6600, STM6601

Waveforms

Figure 10. Unsuccessful power-up on STM6600 (t_{ON_BLANK} expires prior to \overline{PB} release)

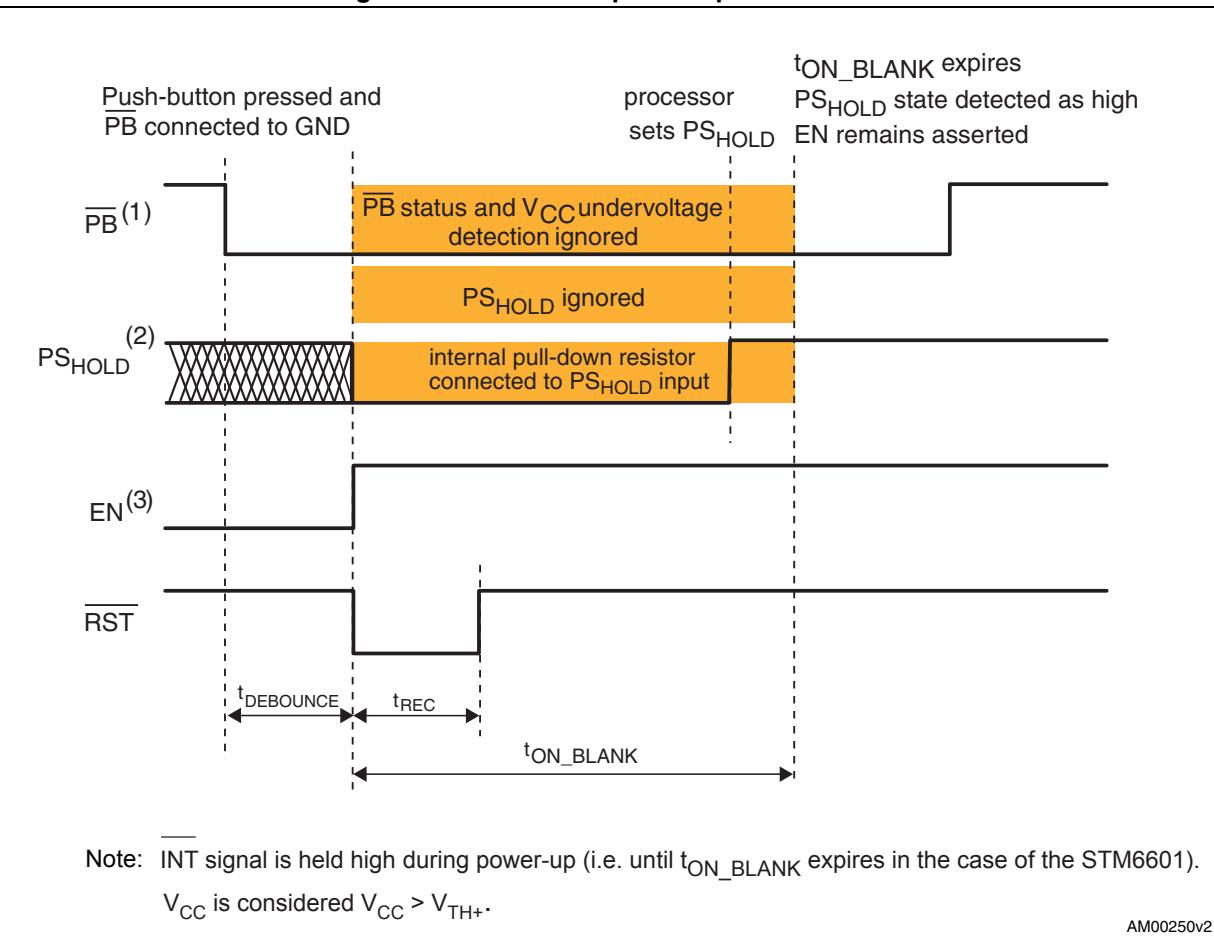


1. \overline{PB} detection on falling and rising edges.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. t_{ON_BLANK} expires prior to \overline{PB} release so PS_{HOLD} is checked at its expiration.

Waveforms

STM6600, STM6601

Figure 11. Successful power-up on STM6601



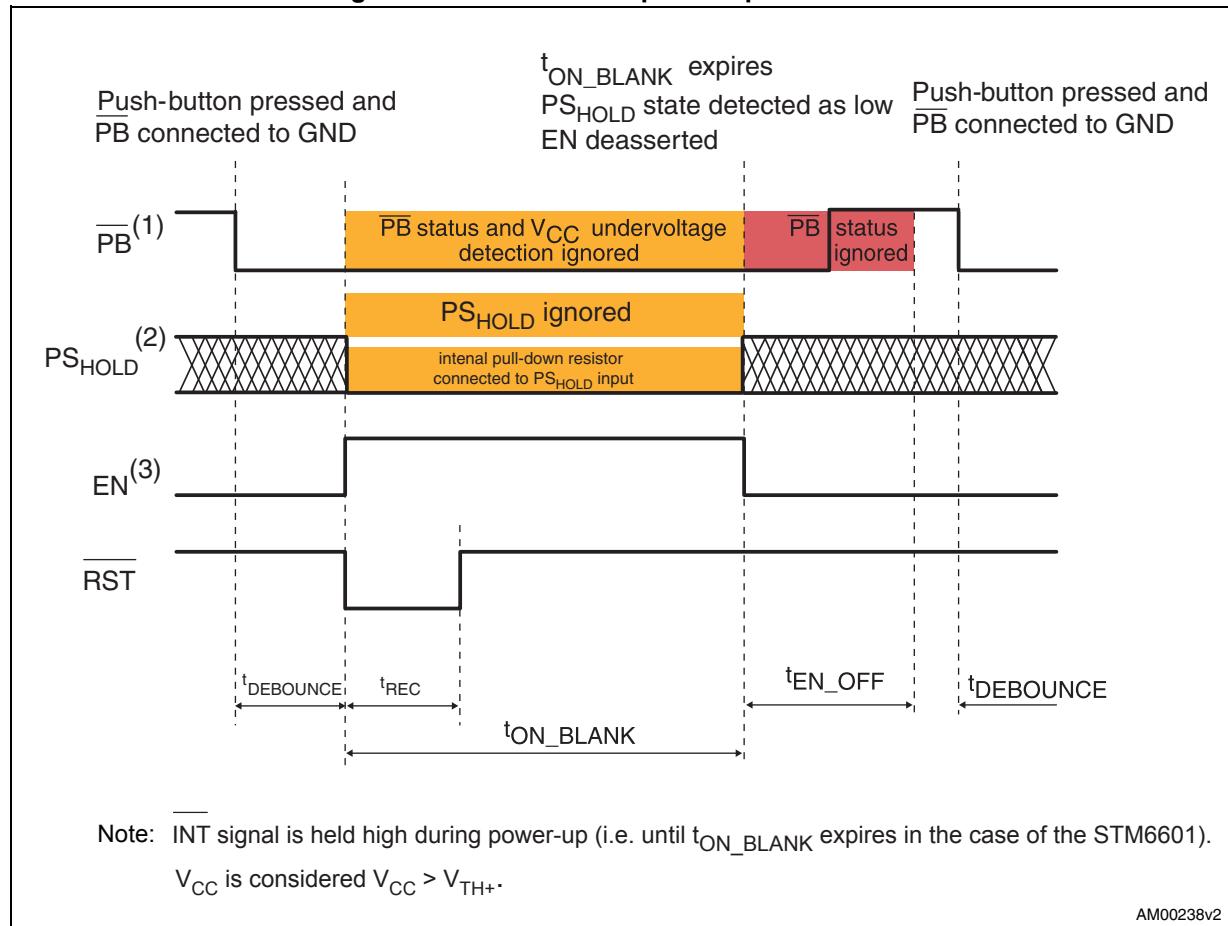
AM00250v2

1. PB detection on falling edge.
2. Internal pull-down resistor 300 kΩ is connected to PS_{HOLD} input during power-up.
3. PS_{HOLD} signal is ignored during t_{ON_BLANK}. When t_{ON_BLANK} expires, the level of the PS_{HOLD} signal is high therefore the EN signal remains asserted.

STM6600, STM6601

Waveforms

Figure 12. Unsuccessful power-up on STM6601

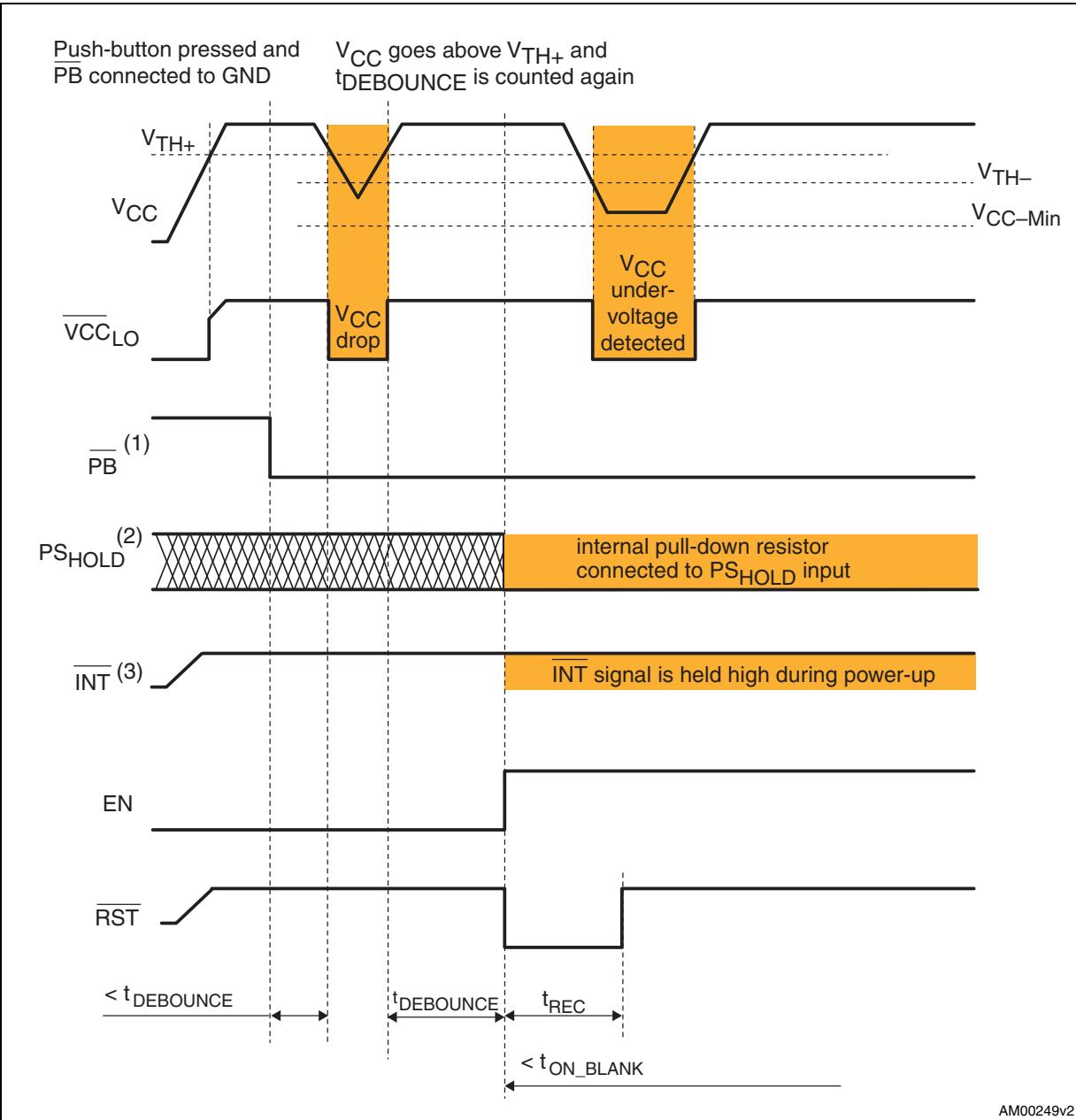


1. $\bar{P}B$ detection on falling edge.
2. Internal pull-down resistor 300 k Ω is connected to PS_{HOLD} input during power-up.
3. PS_{HOLD} signal is ignored during t_{ON_BLANK} . When t_{ON_BLANK} expires, the level of the PS_{HOLD} signal is not high therefore the EN signal goes low. Even releasing the $\bar{P}B$ button after the t_{ON_BLANK} will not prevent this.

Waveforms

STM6600, STM6601

Figure 13. Power-up on STM660x with voltage dropout

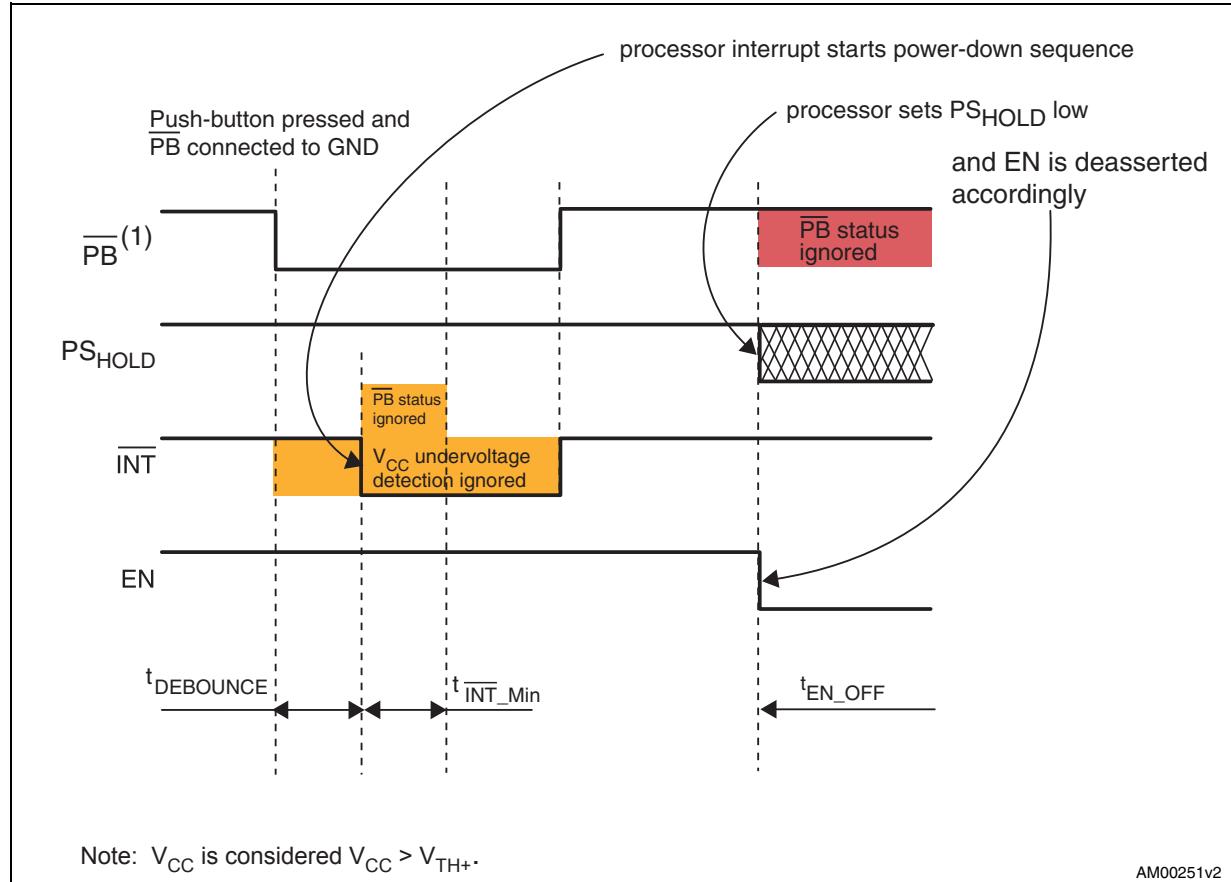


1. PB detection on falling and rising edges.
2. Internal pull-down resistor 300 kΩ is connected to PS_{HOLD} input during power-up.
3. INT signal is held high during power-up.

STM6600, STM6601

Waveforms

Figure 14. PB interrupt



1. PB detection on falling edge.

Waveforms

STM6600, STM6601

Figure 15. Long push, PB pressed first

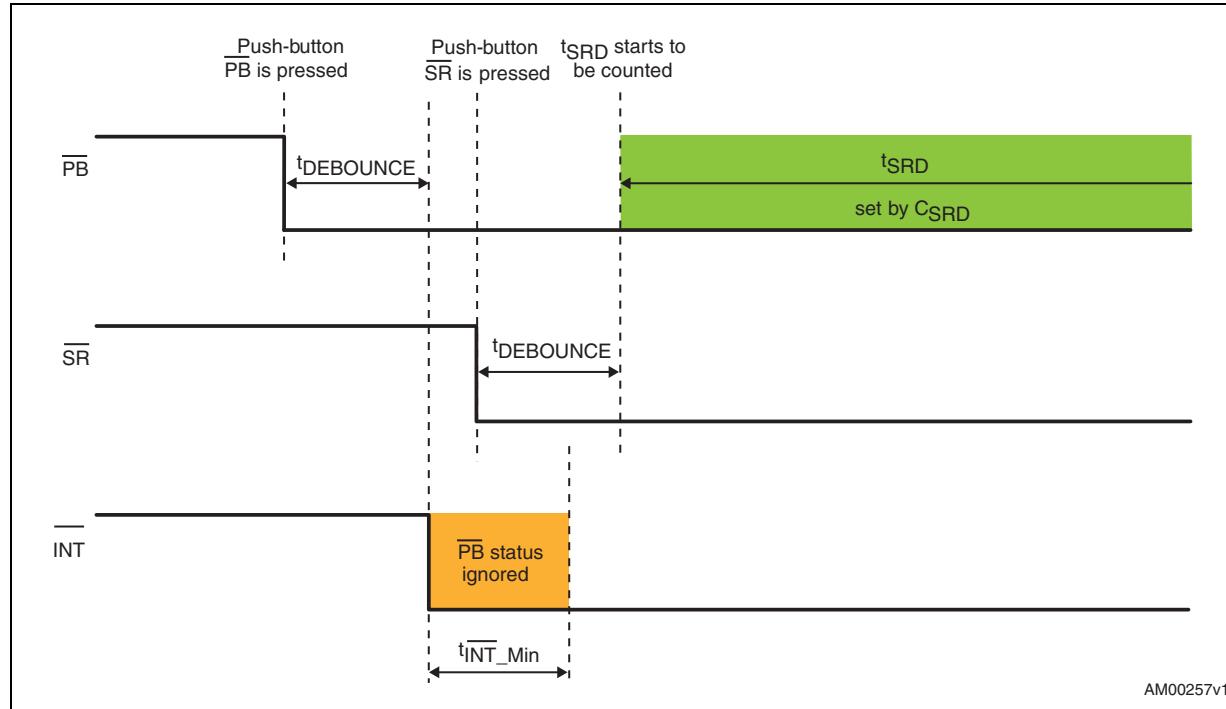
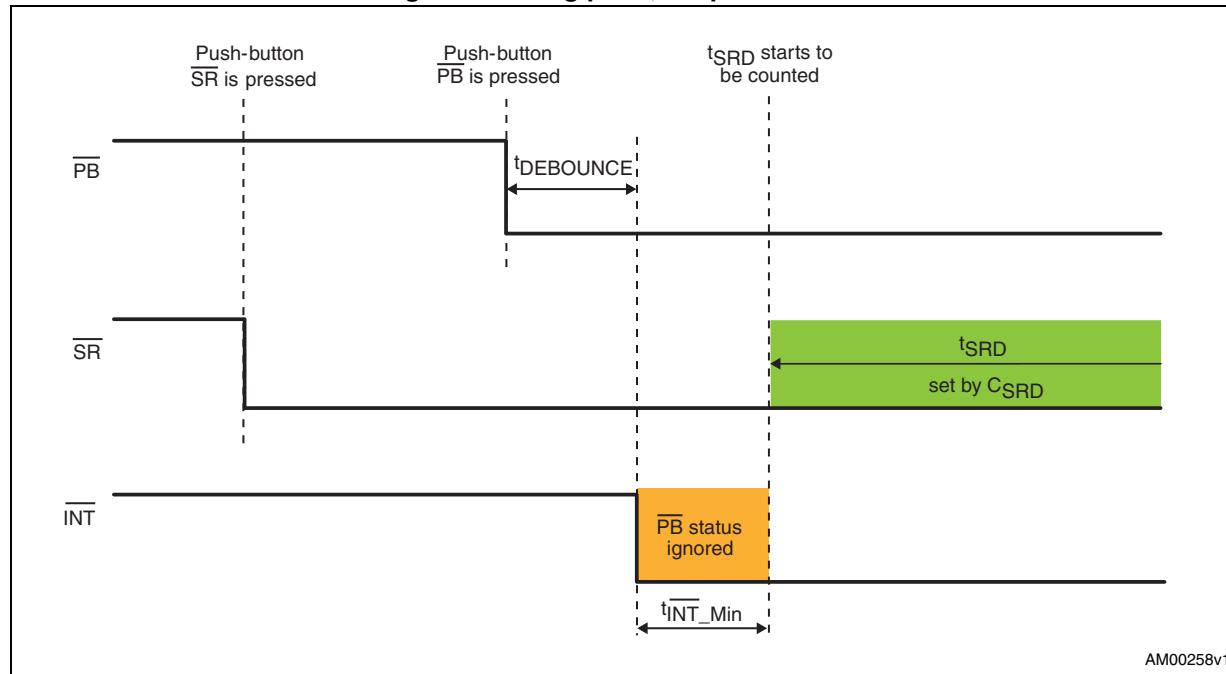


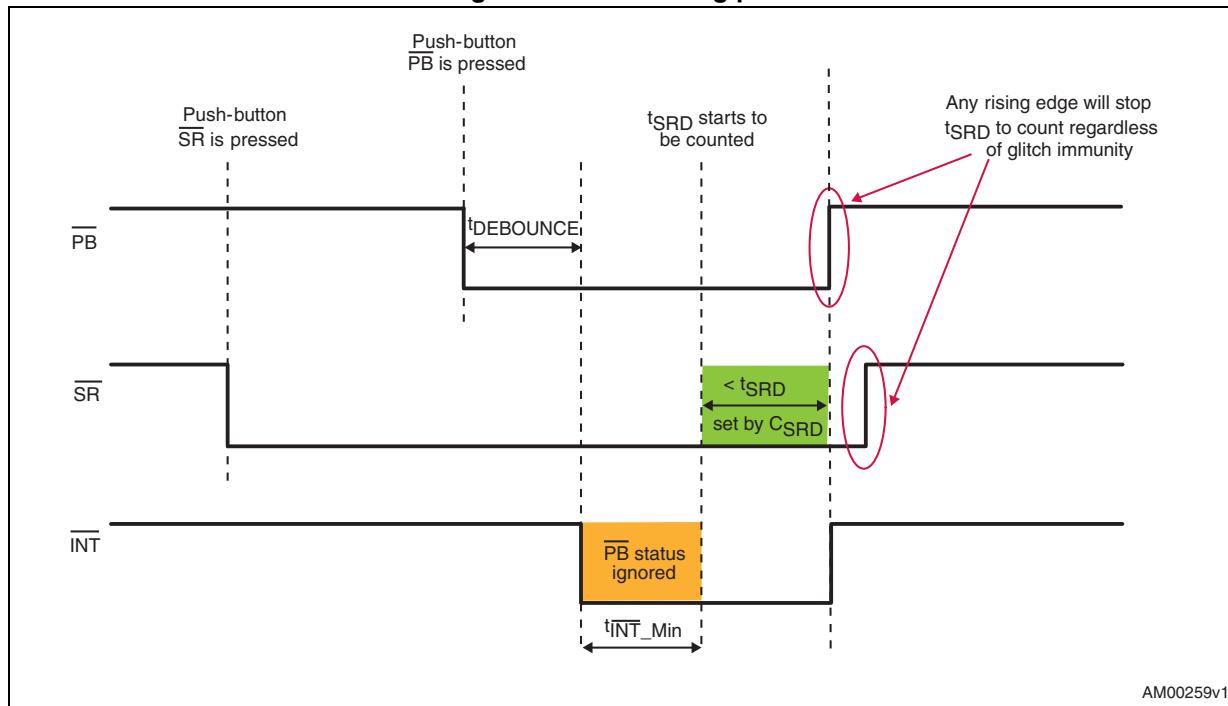
Figure 16. Long push, SR pressed first



STM6600, STM6601

Waveforms

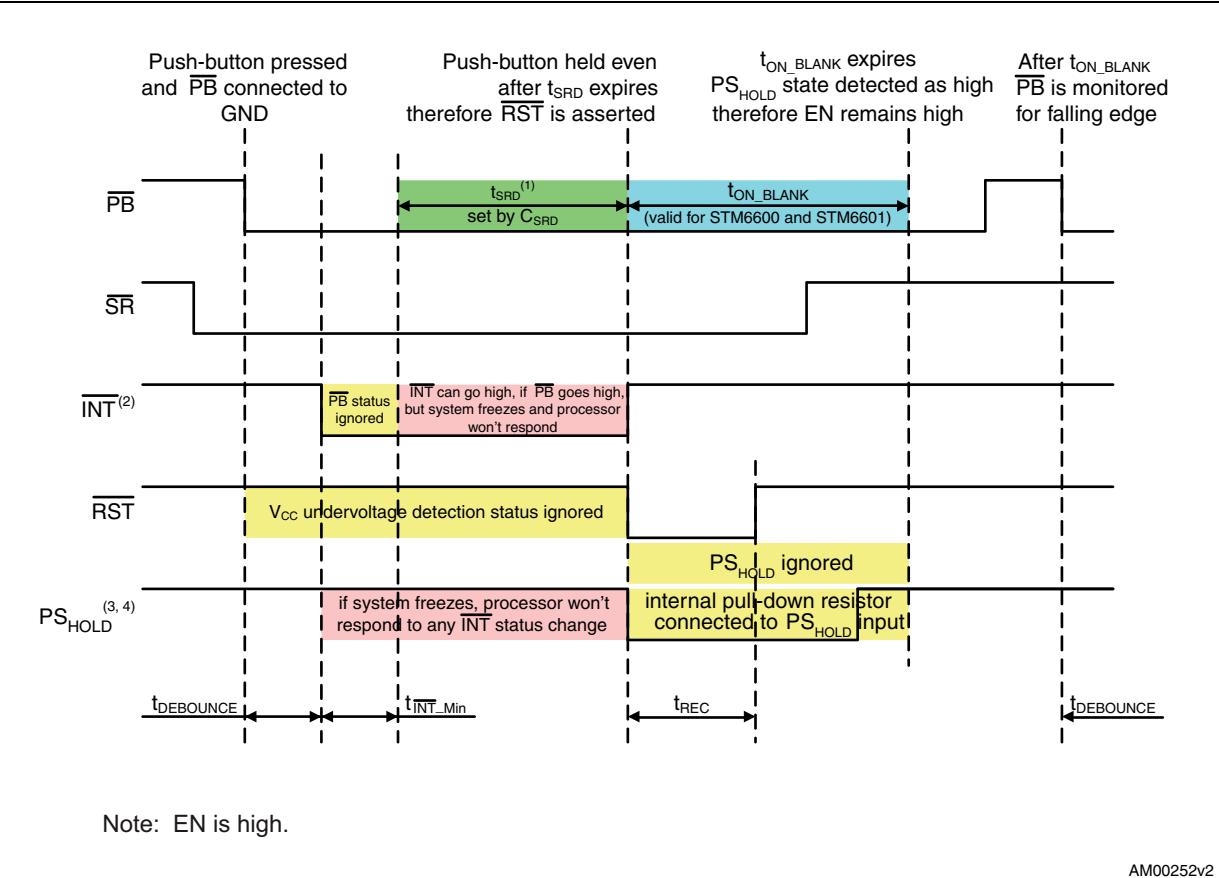
Figure 17. Invalid long push



Waveforms

STM6600, STM6601

Figure 18. Long push (option with RST assertion)

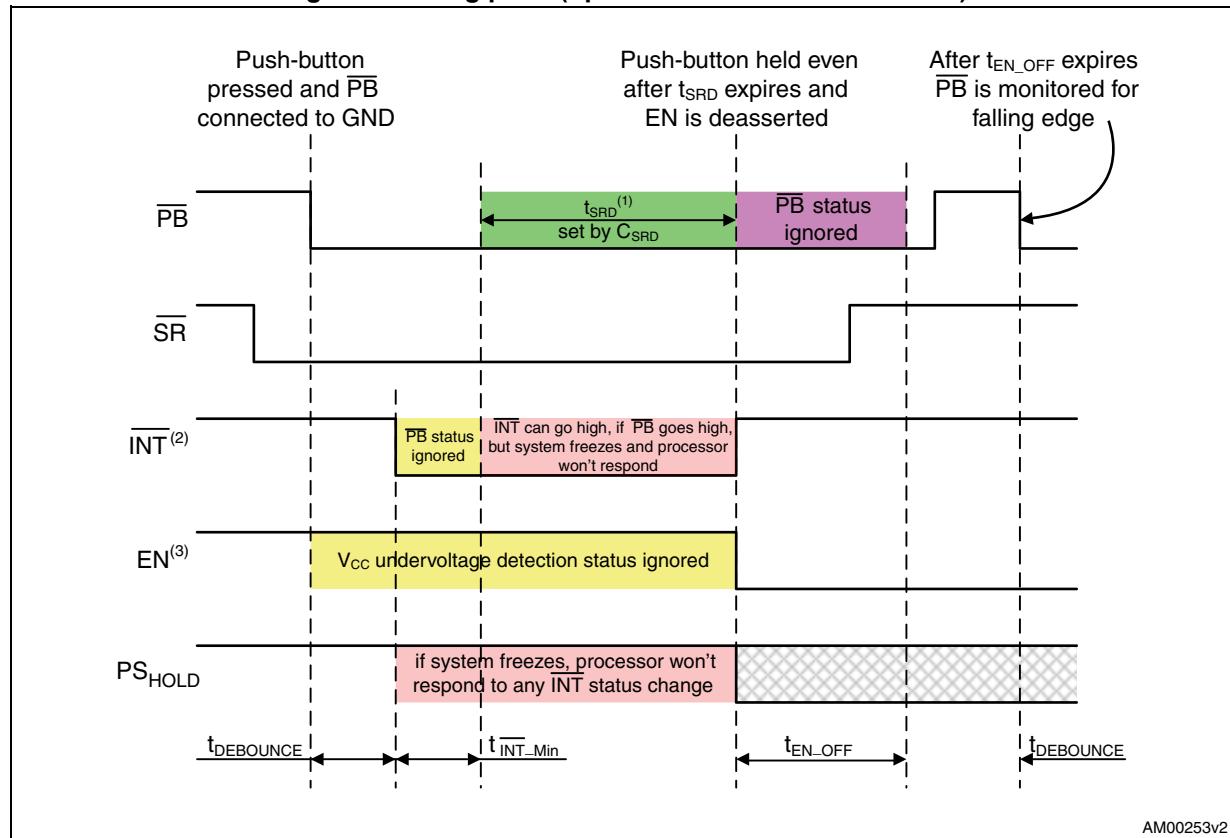


1. t_{SRD} period is set by external capacitor C_{SRD} .
2. \overline{PB} ignored during $t_{\overline{INT_Min}}$.
3. PS_{HOLD} signal is ignored during t_{ON_BLANK} . Its level is checked after t_{ON_BLANK} expires and if it is high the EN signal remains asserted, otherwise EN goes low.
4. Internal pull-down resistor $300\text{ k}\Omega$ is connected to PS_{HOLD} input during startup when device is reset.

STM6600, STM6601

Waveforms

Figure 19. Long push (option with enable deassertion)

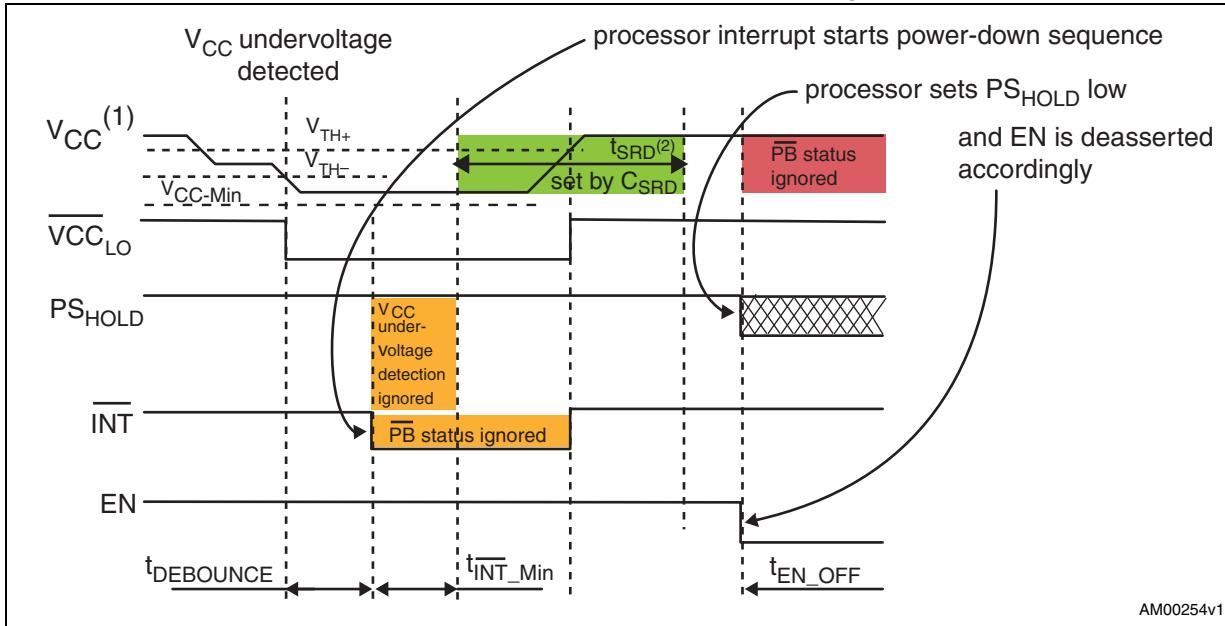


1. t_{SRD} period is set by external capacitor C_{SRD} .
2. \overline{PB} ignored during t_{INT_Min} .
3. After t_{SRD} expires EN is forced low.

Waveforms

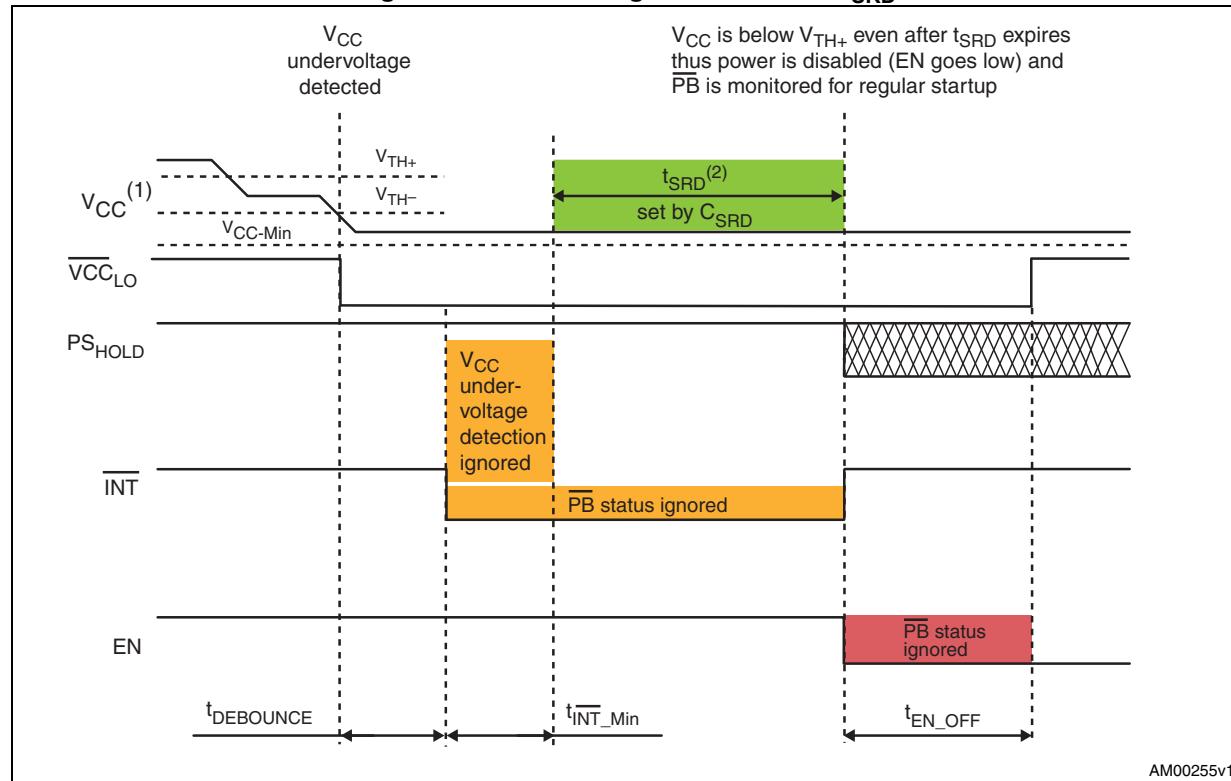
STM6600, STM6601

Figure 20. Undervoltage detected for $t_{SRD} < t_{SRD}$



1. V_{CC} goes above V_{TH+} within t_{SRD} thus power is not disabled after t_{SRD} expires.
2. t_{SRD} period is set by external capacitor C_{SRD} .

Figure 21. Undervoltage detected for $t_{SRD} > t_{SRD}$

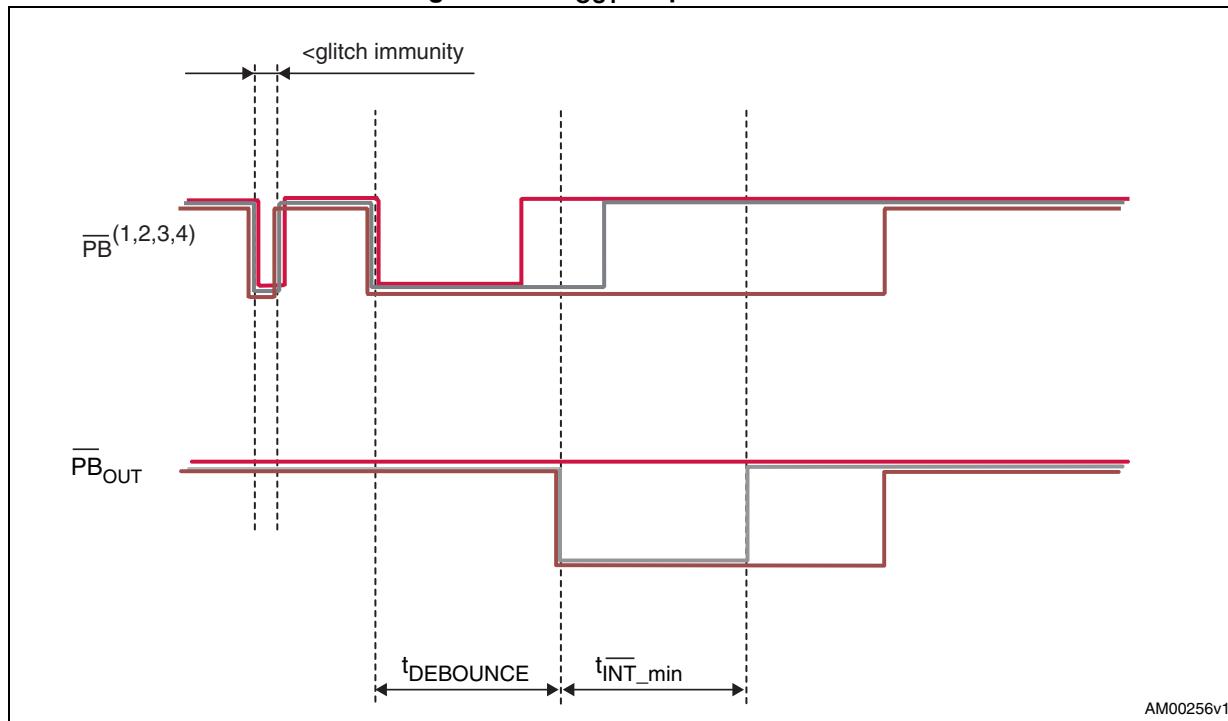


1. After t_{SRD} expires V_{CC} is still insufficient (below V_{TH+}) thus power is disabled (EN goes low or \overline{EN} goes high).
2. t_{SRD} period is set by external capacitor C_{SRD} .

STM6600, STM6601

Waveforms

Figure 22. \overline{PB}_{OUT} output waveform



1. Pulses on \overline{PB} shorter than glitch immunity are ignored.
2. Pulses on \overline{PB} shorter than $t_{DEBOUNCE}$ are not recognized by \overline{PB}_{OUT} .
3. Minimum pulse width on \overline{PB}_{OUT} is t_{INT_Min} .
4. If push-button is held longer than $t_{DEBOUNCE} + t_{INT_Min}$, \overline{PB}_{OUT} goes high when the push-button is released.

Typical operating characteristics

STM6600, STM6601

5 Typical operating characteristics

Figure 23. Supply current vs. temperature, normal state

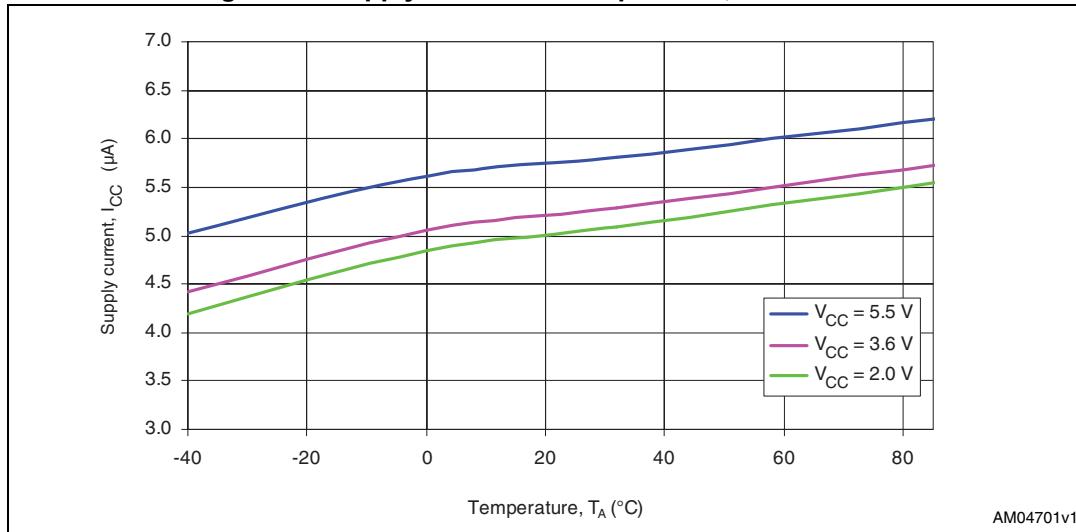
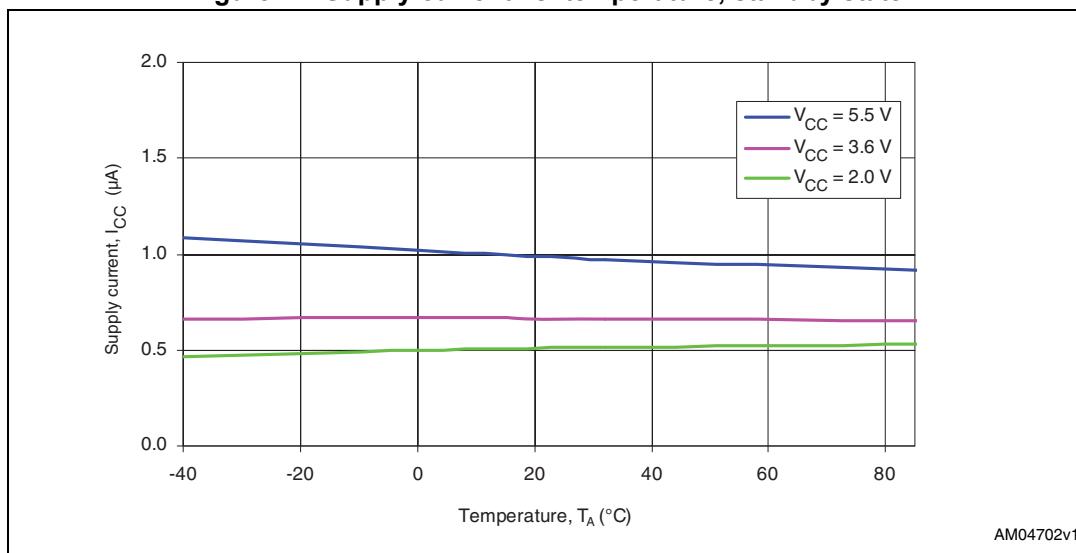


Figure 24. Supply current vs. temperature, standby state



STM6600, STM6601

Typical operating characteristics

Figure 25. Supply current vs. supply voltage, normal state

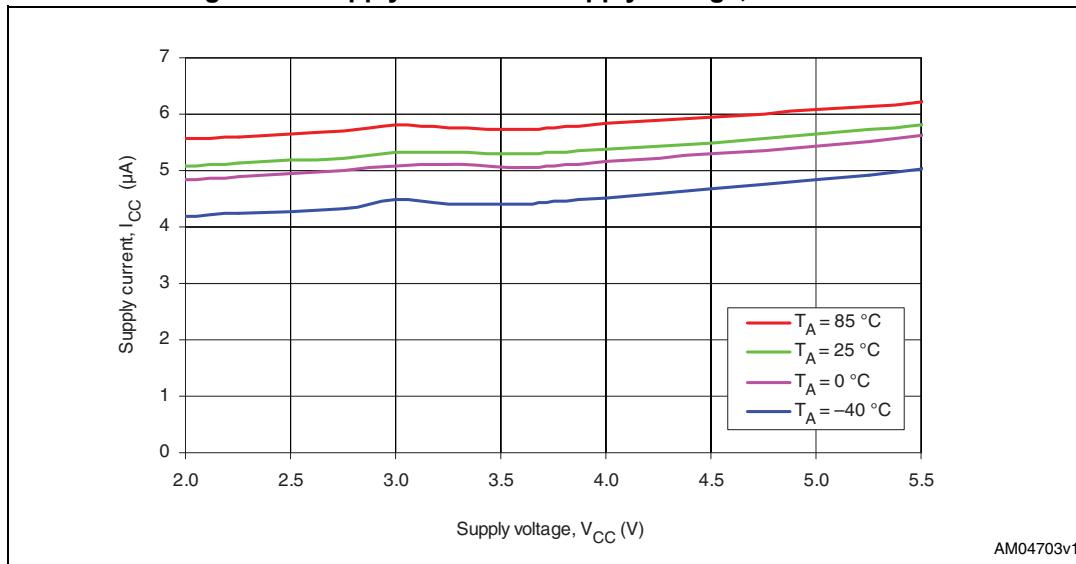
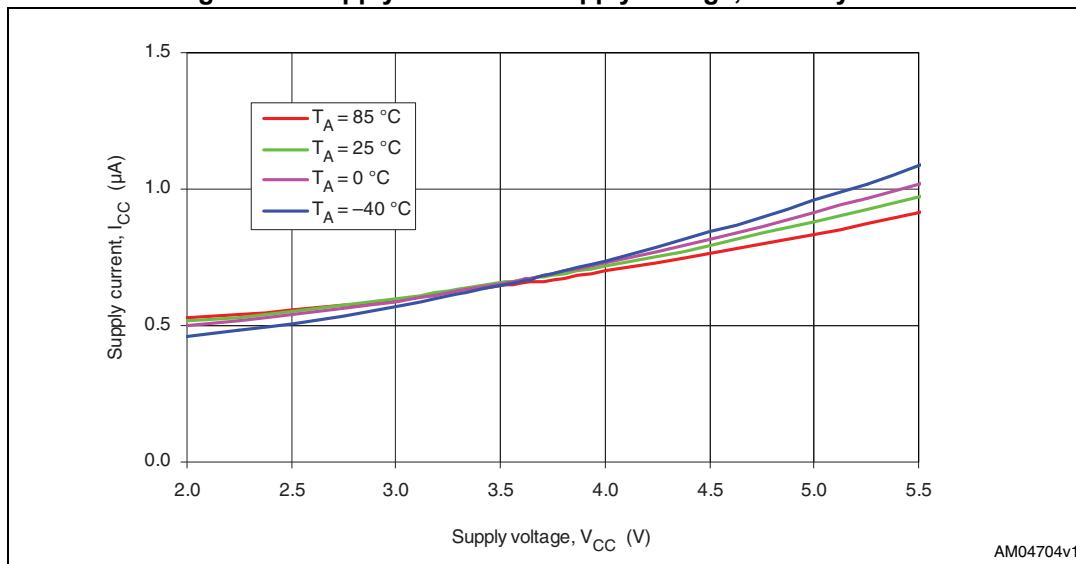


Figure 26. Supply current vs. supply voltage, standby state



Typical operating characteristics

STM6600, STM6601

Figure 27. Threshold vs. temperature, $V_{TH+} = 3.4$ V (typ.)

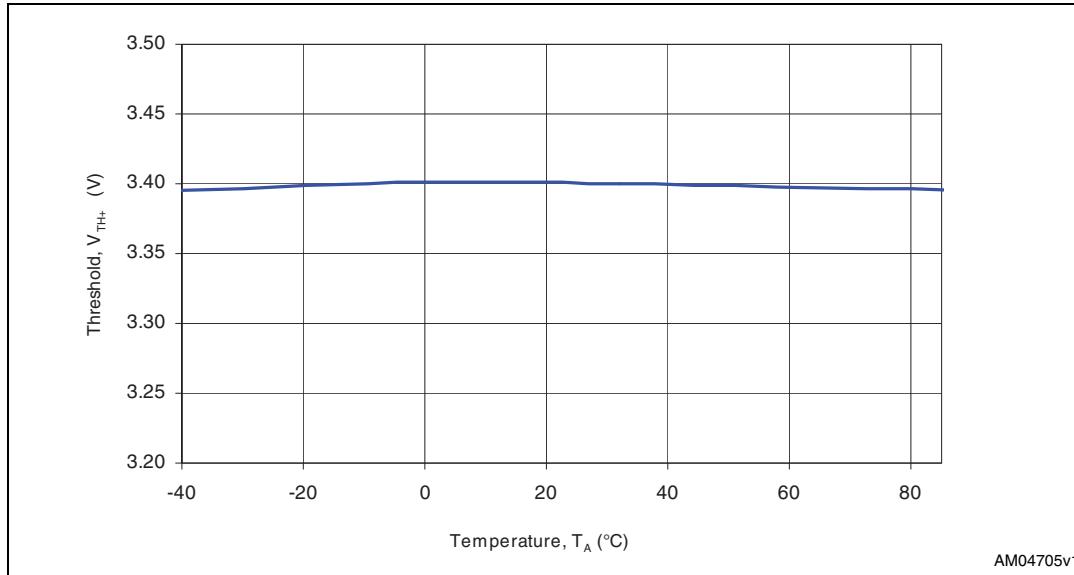
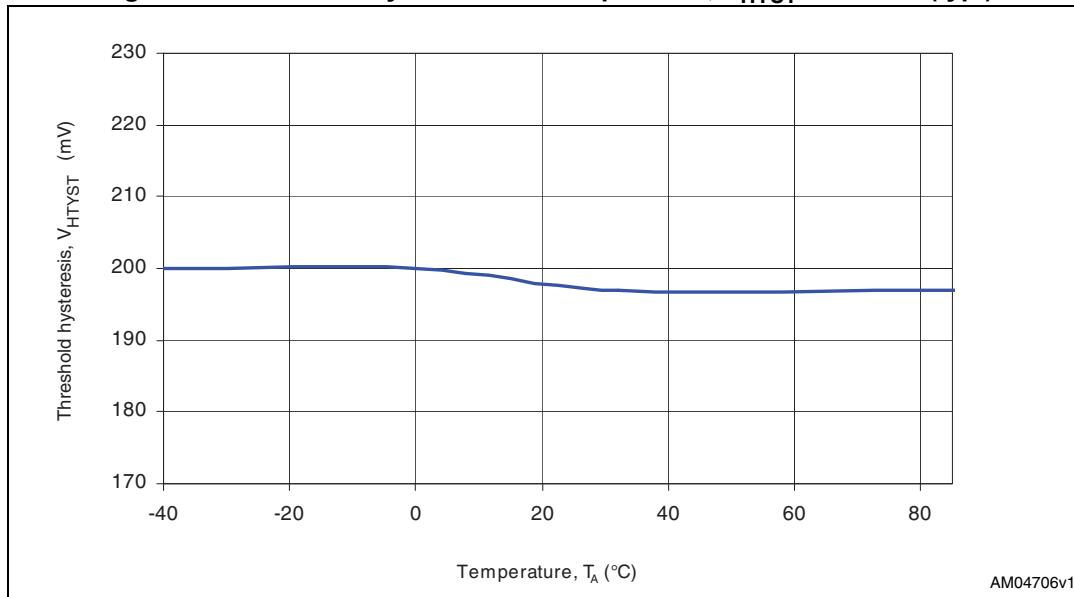


Figure 28. Threshold hysteresis vs. temperature, $V_{HYST} = 200$ mV (typ.)



STM6600, STM6601

Typical operating characteristics

Figure 29. Debounce period vs. supply voltage

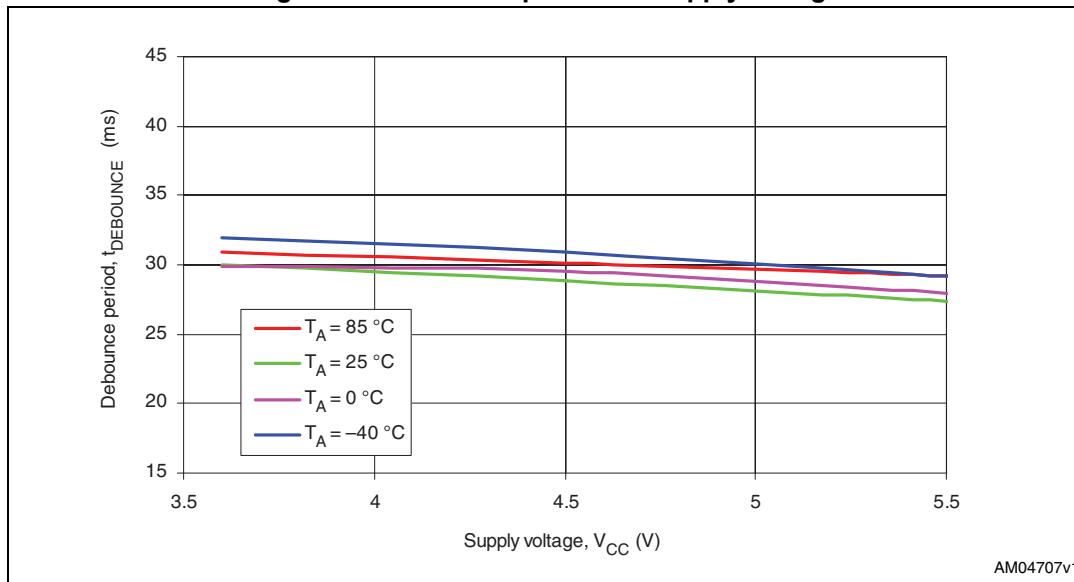
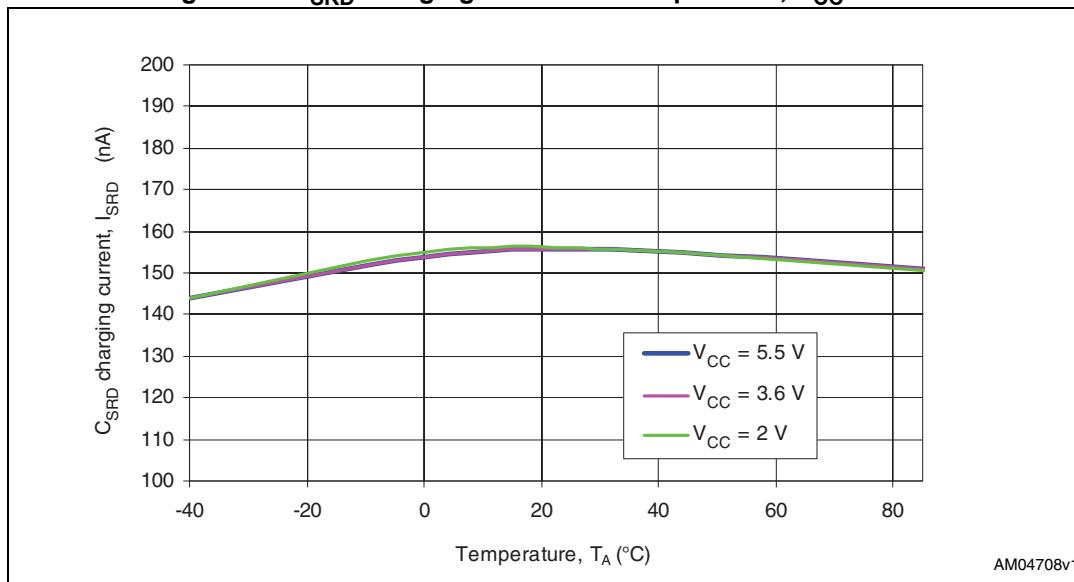


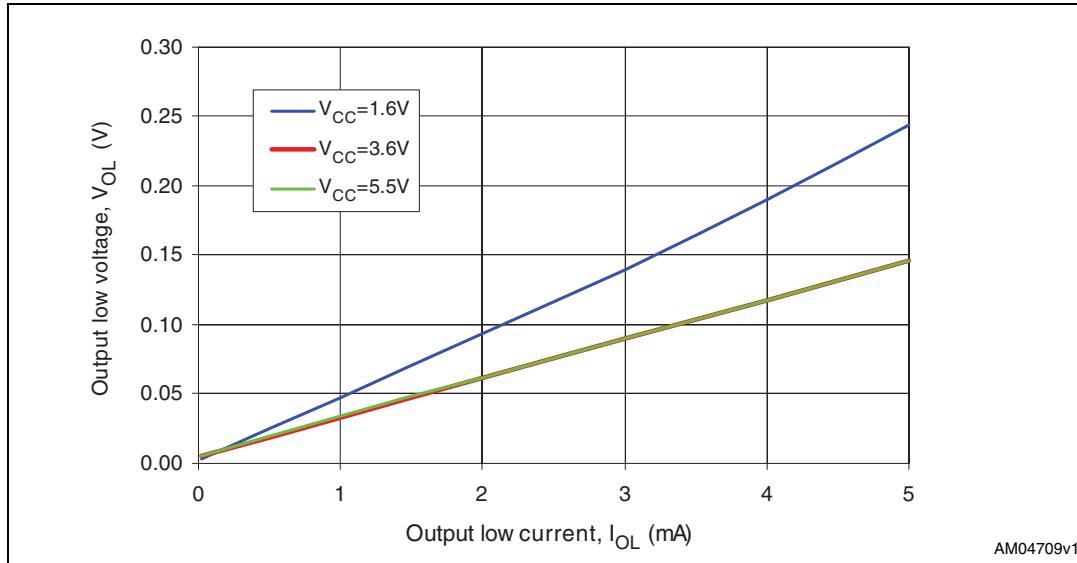
Figure 30. C_{SRD} charging current vs. temperature, $V_{CC} = 3.6\text{ V}$



Typical operating characteristics

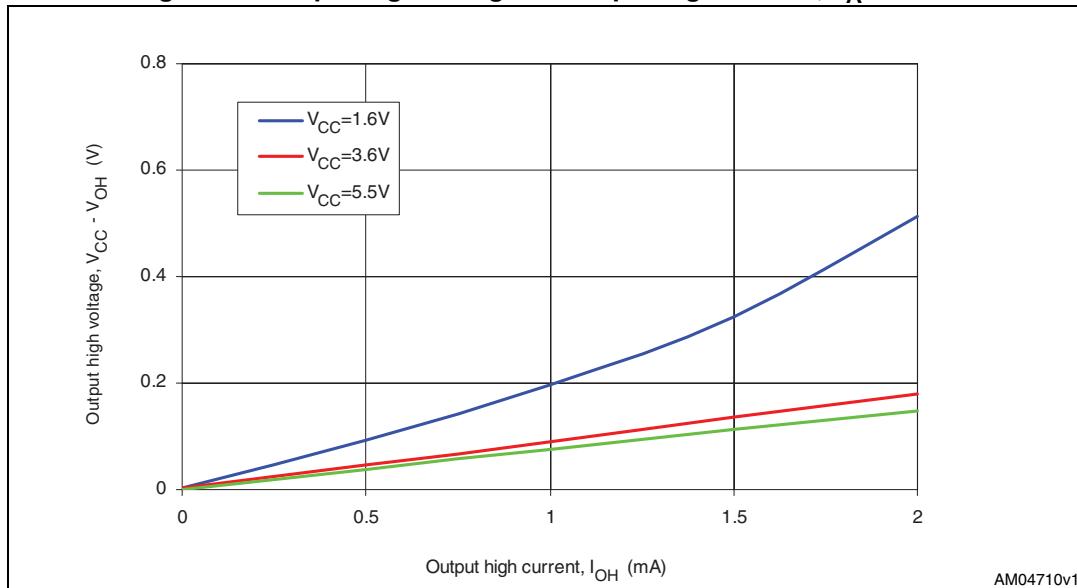
STM6600, STM6601

Figure 31. Output low voltage vs. output low current, $T_A = 25^\circ C$



Note: Characteristics valid for all the outputs (EN , \overline{EN} , RST , INT , PB_{OUT} and \overline{VCC}_{LO}).

Figure 32. Output high voltage vs. output high current, $T_A = 25^\circ C$

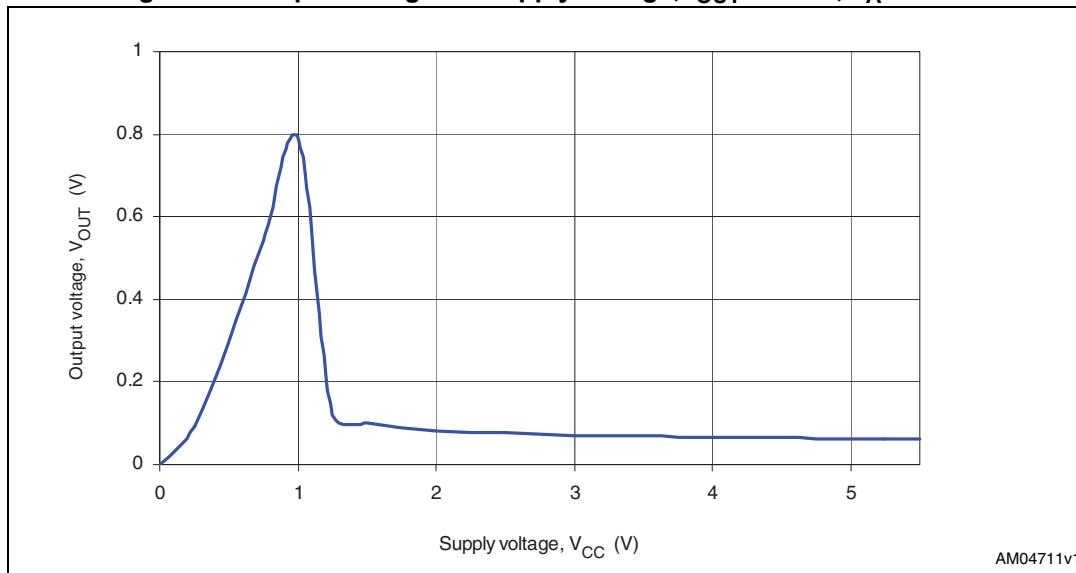


Note: Characteristics valid for EN and \overline{EN} outputs.

STM6600, STM6601

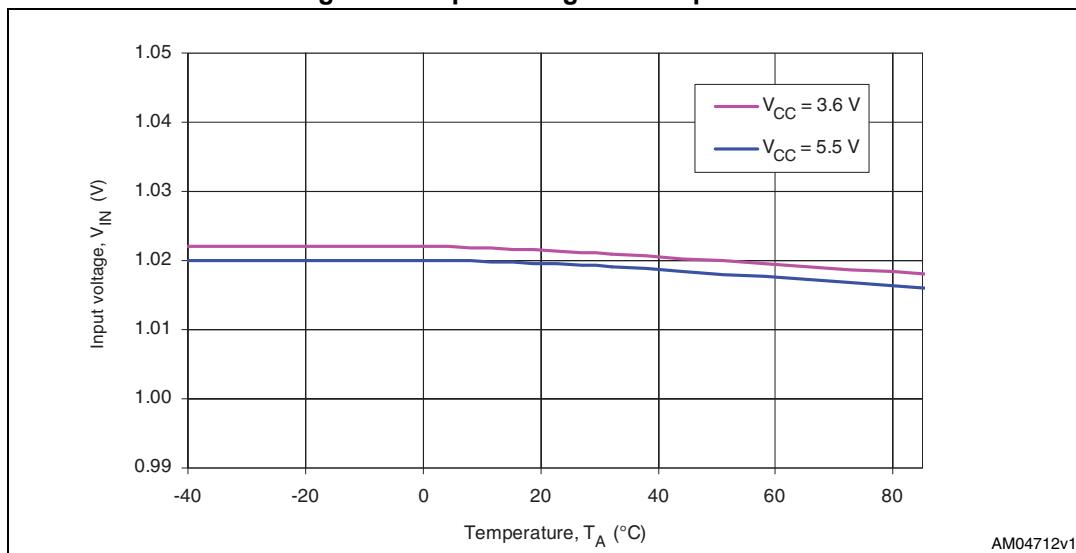
Typical operating characteristics

Figure 33. Output voltage vs. supply voltage, $I_{OUT} = 1 \text{ mA}$, $T_A = 25^\circ\text{C}$



Note: Characteristics valid for all the outputs (EN , \overline{EN} , \overline{RST} , \overline{INT} , \overline{PB}_{OUT} and \overline{VCC}_{LO}).

Figure 34. Input voltage vs. temperature

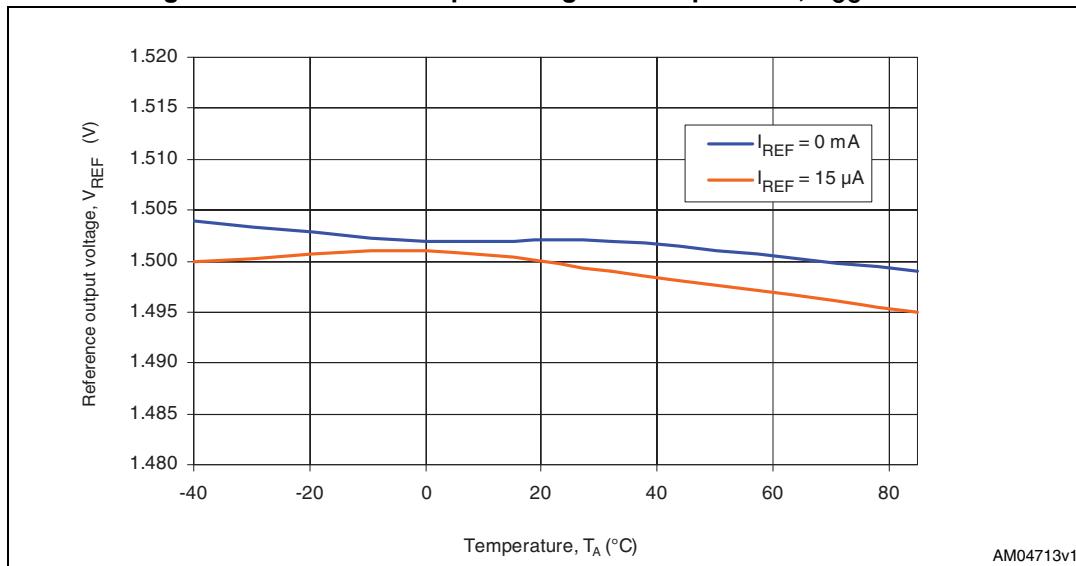


Note: Characteristics valid for \overline{PB} , \overline{SR} and PS_{HOLD} inputs.

Typical operating characteristics

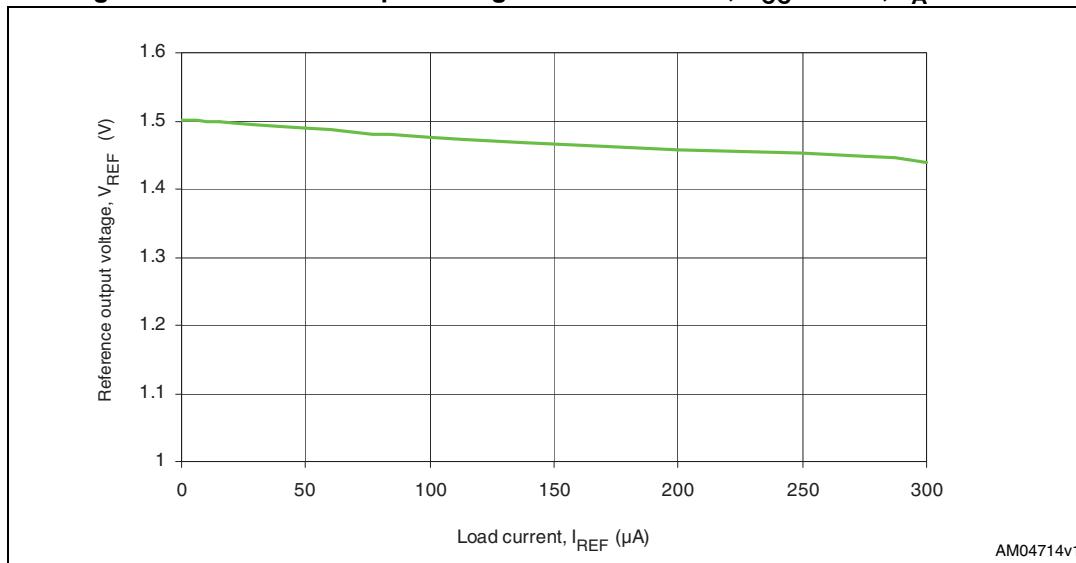
STM6600, STM6601

Figure 35. Reference output voltage vs. temperature, $V_{CC} = 2.0$ V



Note: 1 μ F capacitor is connected to the V_{REF} pin.

Figure 36. Reference output voltage vs. load current, $V_{CC} = 2.0$ V, $T_A = 25$ °C

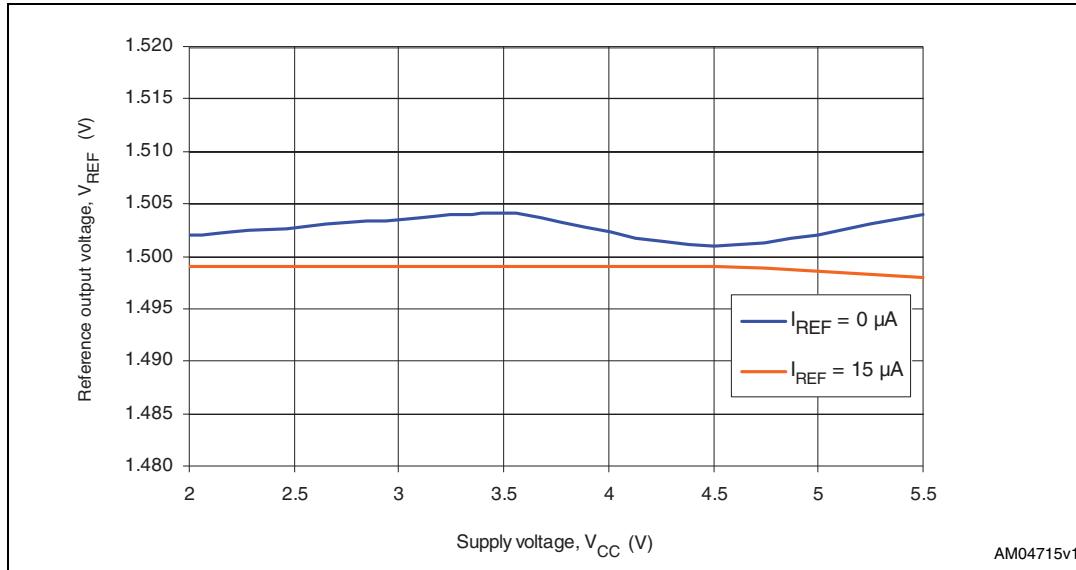


Note: 1 μ F capacitor is connected to the V_{REF} pin.

STM6600, STM6601

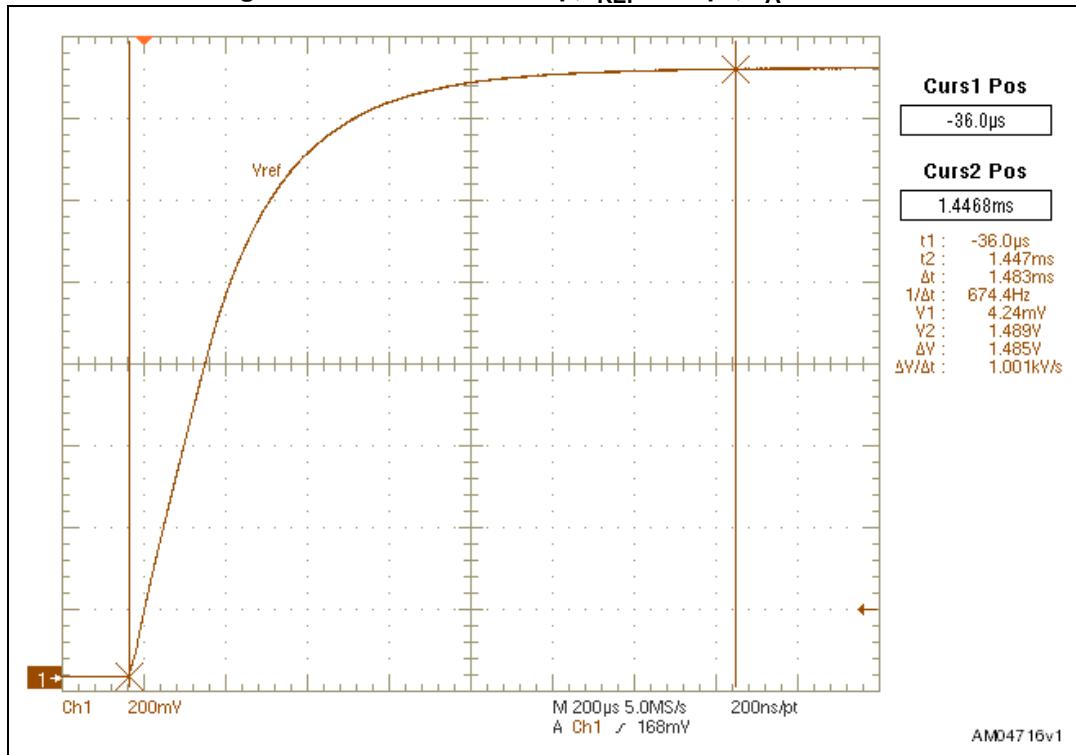
Typical operating characteristics

Figure 37. Reference output voltage vs. supply voltage, $T_A = 25^\circ\text{C}$



Note: 1 μF capacitor is connected to the V_{REF} pin.

Figure 38. Reference startup, $I_{REF} = 15 \mu\text{A}$, $T_A = 25^\circ\text{C}$

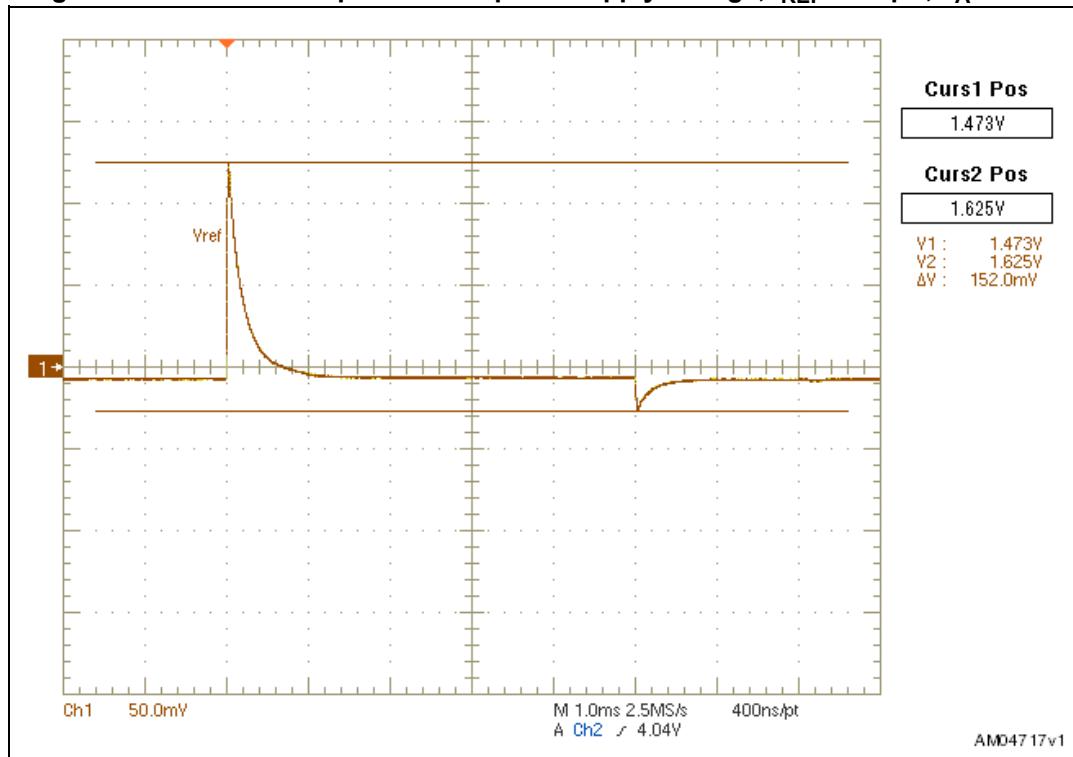


Note: 1 μF capacitor is connected to the V_{REF} pin.

Typical operating characteristics

STM6600, STM6601

Figure 39. Reference response to steps on supply voltage, $I_{REF} = 15 \mu A$, $T_A = 25^\circ C$



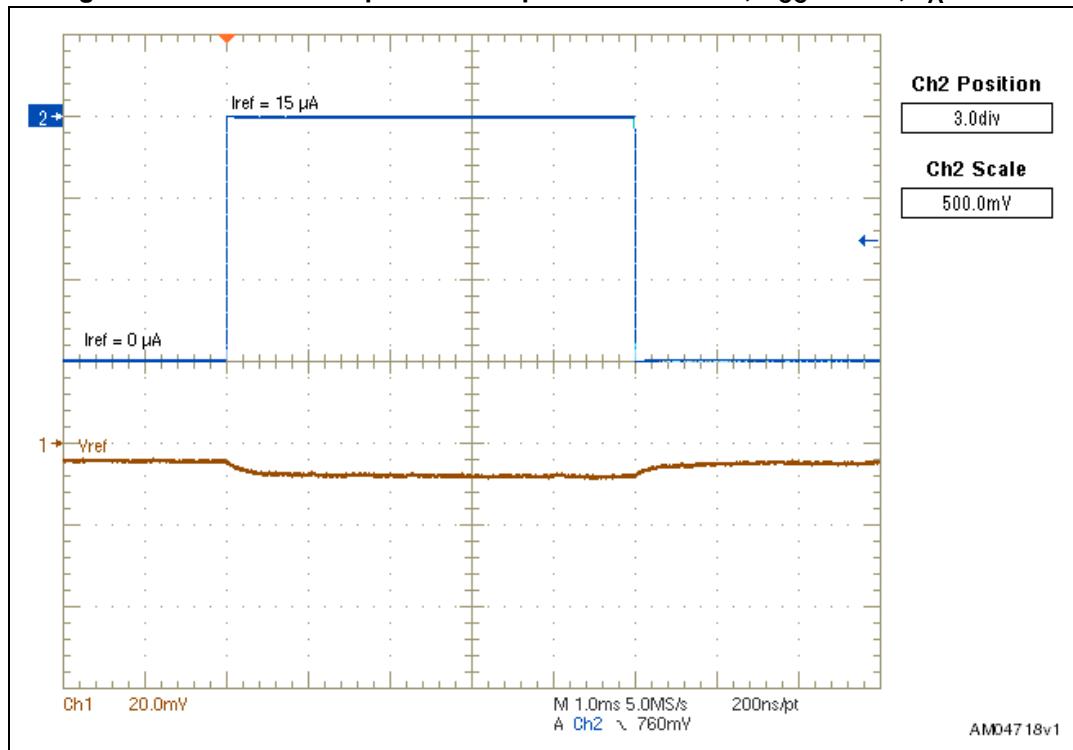
Note:

- 1 Supply voltage goes from 3.6 V to 5.5 V and back to 3.6 V, ramp 1 V / 100 ns.
- 2 1 μF capacitor is connected to the V_{REF} pin.

STM6600, STM6601

Typical operating characteristics

Figure 40. Reference response to steps in load current, $V_{CC} = 3.6$ V, $T_A = 25$ °C



Note: 1 Supply voltage goes from 0 μ A to 15 μ A and back to 0 μ A, ramp 1 μ A / 100 ns.
2 1 μ F capacitor is connected to the V_{REF} pin.

Maximum ratings

STM6600, STM6601

6 Maximum ratings

Stressing the device above the rating listed in [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in [Table 4](#) of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 3. Absolute maximum ratings

Symbol	Parameter	Min.	Max.	Unit	Remarks
V_{CC}	Input supply voltage	-0.3	+7.0	V	
	Input voltages on \overline{PB} , \overline{SR} , PS_{HOLD} and C_{SRD}	-0.3	$V_{CC} + 0.3$	V	
	Output voltages on EN (\overline{EN}), \overline{RST} and INT	-0.3	$V_{CC} + 0.3$	V	
V_{ESD}	Electrostatic protection	-2	+2	kV	Human body model (all pins)
		-8	+8	kV	Human body model (\overline{PB} and \overline{SR})
V_{ESD}	Electrostatic protection	-1000	+1000	V	Charged device model
V_{ESD}	Electrostatic protection	-200	+200	V	Machine model
V_{ESD}	Point discharge on \overline{PB} and \overline{SR} inputs	-8	+8	kV	IEC61000-4-2
V_{ESD}	Air discharge on \overline{PB} and \overline{SR} inputs	-15	+15	kV	IEC61000-4-2
T_A	Operating ambient temperature	-40	+85	°C	
T_{STG}	Storage temperature	-45	+150	°C	
$T_{SLD}^{(1)}$	Lead solder temperature for 10 seconds		+260	°C	
θ_{JA}	Thermal resistance (junction to ambient)		+132.4	°C/W	

1. Reflow at peak temperature of 260 °C. The time above 255 °C must not exceed 30 seconds.

STM6600, STM6601

DC and AC characteristics

7 DC and AC characteristics

This section summarizes the operating measurement conditions and the DC and AC characteristics of the device. The parameters in [Table 5](#) that follow are derived from tests performed under the measurement conditions summarized in [Table 4](#). Designers should check that the operating conditions in their circuit match the operating conditions when relying on the quoted parameters.

Table 4. Operating and AC measurement conditions

Parameter	Condition	Unit
V_{CC} supply voltage	1.6 to 5.5	V
Ambient operating temperature (T_A)	-40 to 85	°C
Input rise and fall times	≤ 5	ns

Table 5. DC and AC characteristics

Symbol	Parameter	Test condition ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
V_{CC}	Supply voltage		1.6		5.5	V
I_{CC}	Supply current	$V_{CC} = 3.6$ V, no load		6.0	8.0	μA
		Standby mode, enable deasserted, $V_{CC} = 3.6$ V		0.6	1.0	μA
V_{TH+}	Power-on lockout voltage (see Table 10 for detailed listing)		2.40	2.50	2.60	V
			3.00	3.10	3.20	
			3.20	3.30	3.40	
			3.29	3.40	3.51	
			3.39	3.50	3.61	
V_{HYST}	Threshold hysteresis (see Table 10 for detailed listing)			200		mV
				500		
V_{TH-}	Forced power-off voltage (see Table 10 for detailed listing)			$V_{TH+} - V_{HYST}$		V
t_{TH-}	Undervoltage detection to INT delay	$V_{CC} \geq 2.0$ V	20	32	44	ms
t_{ON_BLANK}	Blanking period (see Table 10 for detailed listing) ⁽³⁾		1.4	2.2	3.0	s
			5.6	8.8	12.0	
			11.2	17.6	24.0	
	RST assertion to EN (EN) assertion delay during power-up	$V_{CC} = 3.6$ V		100		ns

DC and AC characteristics

STM6600, STM6601

Table 5. DC and AC characteristics (continued)

Symbol	Parameter	Test condition ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
PB						
V_{IL}	Input low voltage	$V_{CC} \geq 2.0$ V, enable asserted			0.99	V
V_{IH}	Input high voltage	$V_{CC} \geq 2.0$ V, enable asserted	1.05			V
$t_{DEBOUNCE}$	Debounce period	$V_{CC} \geq 2.0$ V	20	32	44	ms
R_{PB}	Internal pull-up resistor	$V_{CC} = 5.5$ V, input asserted	65	100	135	k Ω
SR						
V_{IL}	Input low voltage				0.99	V
V_{IH}	Input high voltage		1.05			V
$t_{DEBOUNCE}$	Debounce period		20	32	44	ms
$R_{SR}^{(4)}$	Internal pull-up resistor	$V_{CC} = 5.5$ V, input asserted	65	100	135	k Ω
PB_{OUT}						
V_{OL}	Output low voltage	$V_{CC} = 2$ V, $I_{SINK} = 1$ mA, PB_{OUT} asserted			0.3	V
	PB_{OUT} leakage current	$V_{PB_{OUT}} = 3$ V, PB_{OUT} open drain	-0.1		+0.1	μ A
V_{CC_{LO}}						
V_{OL}	Output low voltage	$V_{CC} = 2$ V, $I_{SINK} = 1$ mA, VCC_{LO} asserted			0.3	V
	VCC_{LO} leakage current	$V_{VCC_{LO}} = 3$ V, VCC_{LO} open drain	-0.1		+0.1	μ A
PS_{HOLD}						
V_{IL}	Input low voltage	$V_{CC} \geq 2.0$ V			0.99	V
V_{IH}	Input high voltage	$V_{CC} \geq 2.0$ V	1.05			V
	Glitch immunity		1	80		μ s
	PS _{HOLD} leakage current	$V_{PSHOLD} = 0.6$ V	-0.1		0.1	μ A
	PS _{HOLD} to enable propagation delay				30	μ s
R_{PSHOLD}	Pull-down resistor connected internally during power-up	$V_{PSHOLD} = 5.5$ V	195	300	405	k Ω

STM6600, STM6601

DC and AC characteristics

Table 5. DC and AC characteristics (continued)

Symbol	Parameter	Test condition ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
C_{SRD}						
I _{SRD}	C _{SRD} charging current		100	150	200	nA
V _{SRD}	C _{SRD} voltage threshold	V _{CC} = 3.6 V, load on V _{REF} pin 100 kΩ and mandatory 1 μF capacitor, T _A = 25 °C		1.5		V
t _{SRD}	Additional Smart Reset TM delay time	External C _{SRD} connected		10		s/μF
EN, \overline{EN}						
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, enable asserted			0.3	V
V _{OH} ⁽⁵⁾	Output high voltage	V _{CC} = 2 V, I _{SOURCE} = 1 mA, enable asserted	V _{CC} – 0.3			V
t _{EN_OFF} ⁽⁶⁾	enable off to enable on	V _{CC} ≥ 2.0 V	40	64	88	ms
	EN, \overline{EN} leakage current	V _{EN} = 2 V, enable open drain	–0.1		+0.1	μA
RST						
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, RST asserted			0.3	V
t _{REC}	RST pulse width	V _{CC} ≥ 2.0 V	240	360	480	ms
	RST leakage current	V _{RST} = 3 V	–0.1		+0.1	μA
INT						
V _{OL}	Output low voltage	V _{CC} = 2 V, I _{SINK} = 1 mA, INT asserted			0.3	V
t _{INT_Min}	Minimum INT pulse width	V _{CC} ≥ 2.0 V	20	32	44	ms
	INT leakage current	V _{INT} = 3 V	–0.1		+0.1	μA
V_{REF}						
V _{REF}	1.5 V voltage reference	V _{CC} = 3.6 V, load on V _{REF} pin 100 kΩ and mandatory 1 μF capacitor, T _A = 25 °C	1.485 –1%	1.5	1.515 +1%	V

1. Valid for ambient operating temperature: T_A = –40 to 85 °C; V_{CC} = 1.6 V to 5.5 V (except where noted).
2. Typical values are at T_A = +25 °C.
3. This blanking time allows the processor to start up correctly (see [Figure 7, 8, 9, 10, 11, 12](#)).
4. The internal pull-up resistor connected to the \overline{SR} input is optional (see [Table 10](#) for detailed device options).
5. Valid for push-pull only.
6. Minimum delay time between enable deassertion and enable reassertion, allowing the application to complete the power-down properly. PB is ignored during this period.

Package mechanical data**STM6600, STM6601****8 Package mechanical data**

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

STM6600, STM6601

Package mechanical data

Figure 41. TDFN12 (2 x 3 mm) package outline

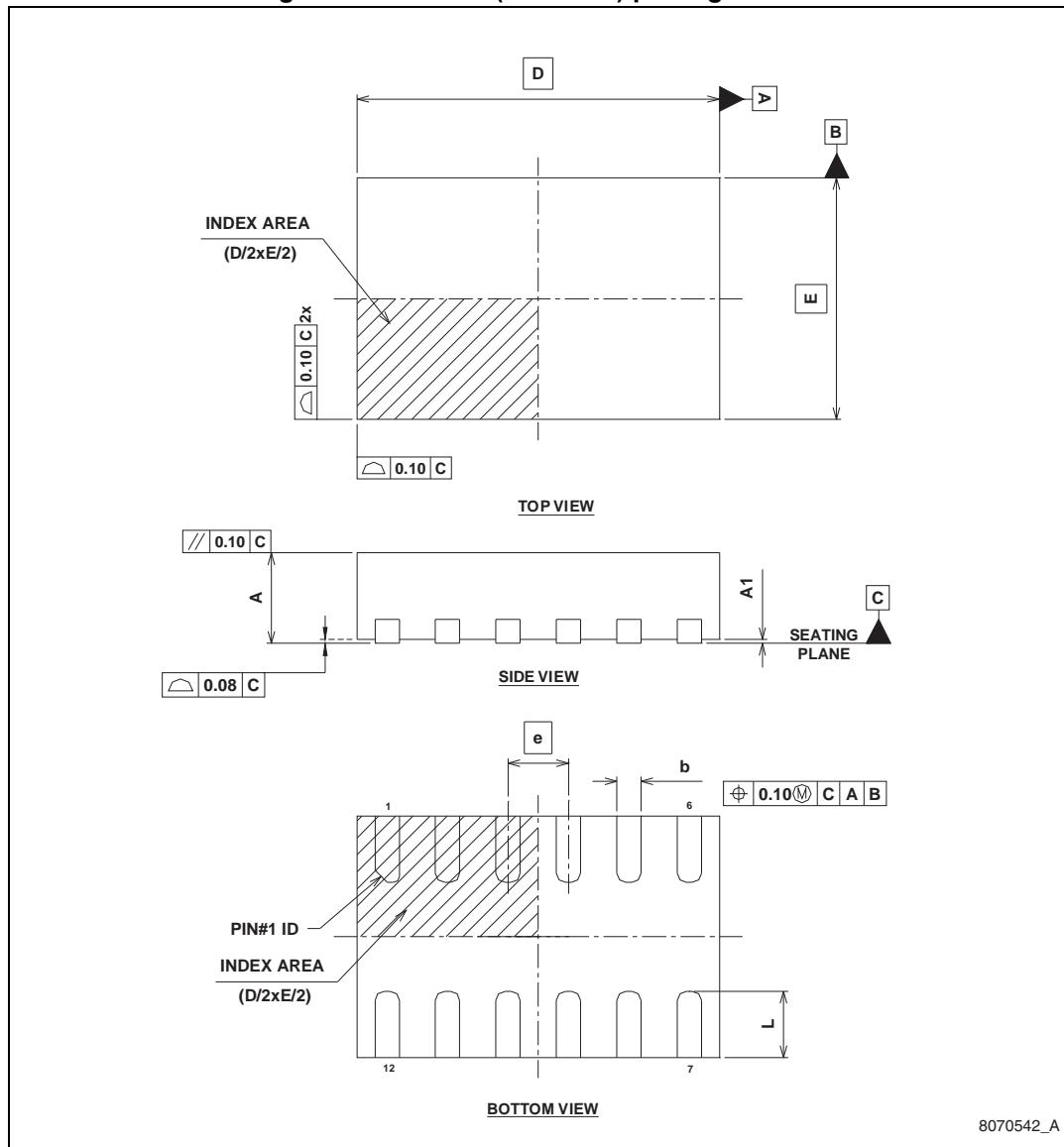


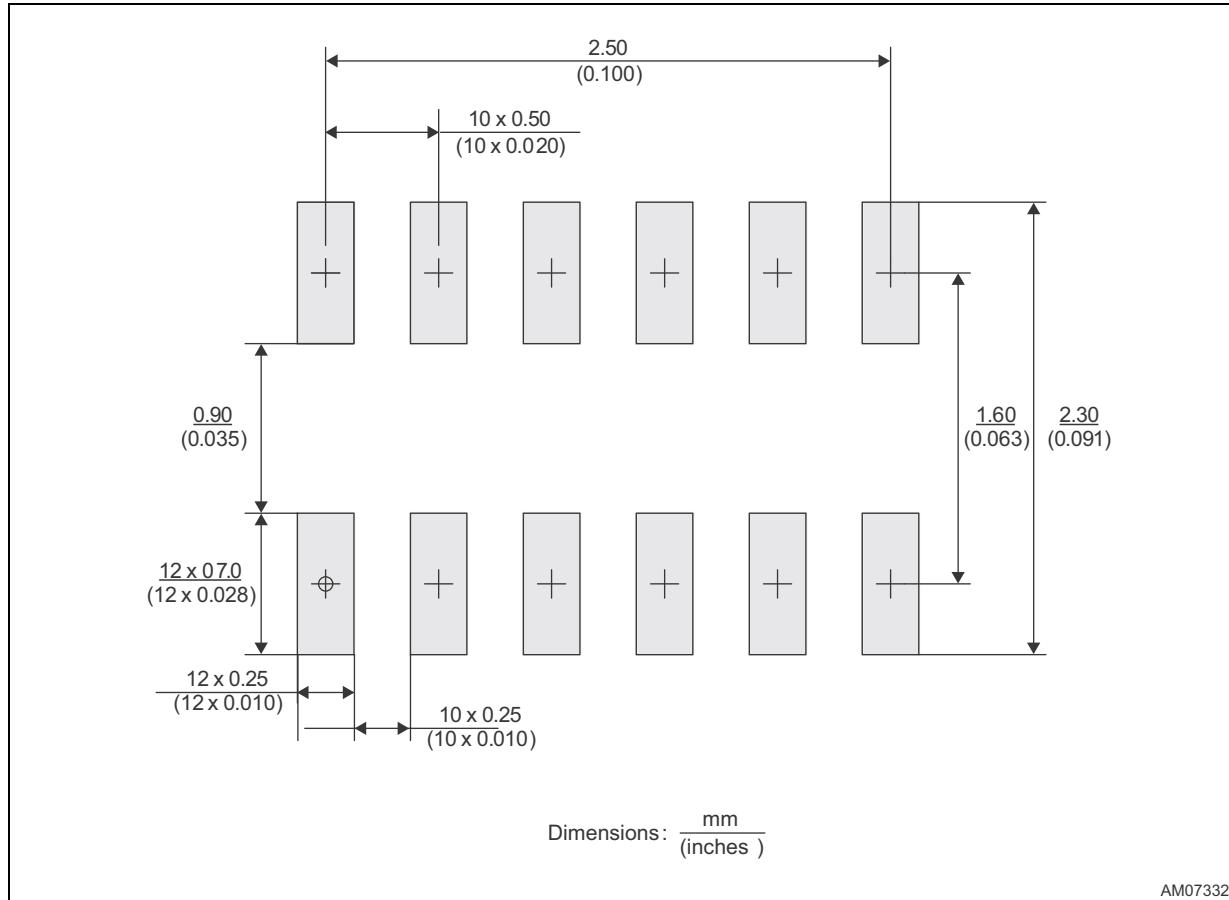
Table 6. TDFN12 (2 x 3 mm) package mechanical data

Symbol	mm			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
D		3.00 BSC			0.118	
E		2.00 BSC			0.079	
e		0.50			0.020	
L	0.45	0.55	0.65	0.018	0.022	0.026

Package mechanical data

STM6600, STM6601

Figure 42. TDFN12 (2 x 3 mm) recommended footprint



Note: Drawing not to scale.

STM6600, STM6601

Package mechanical data

Figure 43. Carrier tape for TDFN12 (2 x 3 mm) package

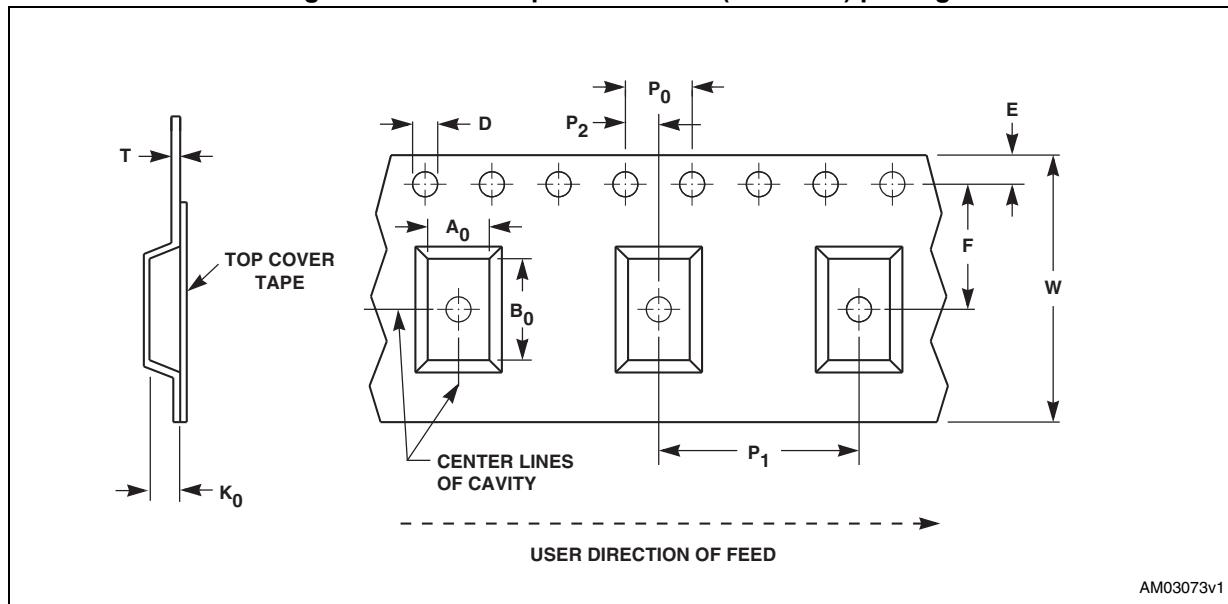


Table 7. Carrier tape dimensions for TDFN12 (2 x 3 mm) package

Package	W	D	E	P ₀	P ₂	F	A ₀	B ₀	K ₀	P ₁	T	Unit	Bulk qty.
TDFN12	12.00 ±0.30	1.50 +0.10/ -0.00	1.75 ±0.10	4.00 ±0.10	2.00 ±0.10	5.50 ±0.05	2.30 ±0.10	3.20 ±0.10	1.10 ±0.01	4.00 ±0.10	0.30 ±0.05	mm	3000

Part numbering

STM6600, STM6601

9 Part numbering

Table 8. STM6600 ordering information scheme

Example:	STM660	0	F	Q	2	4	DM	6	F
Device type									
STM660									
Startup process									
0: PB must be held low until the PS _{HOLD} confirmation									
Input and output types⁽¹⁾									
A: active high EN output, long push asserts \overline{RST} , pull-up on \overline{SR}									
B: active low \overline{EN} output, long push asserts \overline{RST} , pull-up on \overline{SR}									
C: active high EN output, long push deasserts EN, pull-up on \overline{SR}									
D: active low \overline{EN} output, long push deasserts \overline{EN} , pull-up on \overline{SR}									
E: active high EN output, long push asserts \overline{RST} , no resistor on \overline{SR}									
F: active low \overline{EN} output, long push asserts \overline{RST} , no resistor on \overline{SR}									
G: active high EN output, long push deasserts EN, no resistor on \overline{SR}									
H: active low \overline{EN} output, long push deasserts \overline{EN} , no resistor on \overline{SR}									
V_{TH+} threshold voltage⁽¹⁾									
A: 2.50 V									
Q: 3.30 V									
S: 3.40 V									
U: 3.50 V									
V_{HYST} voltage hysteresis⁽¹⁾									
2: 200 mV									
5: 500 mV									
t_{ON_BLANK} blanking period⁽¹⁾									
2: 1.4 s (min.)									
4: 5.6 s (min.)									
5: 11.2 s (min.)									

STM6600, STM6601**Part numbering****Table 8. STM6600 ordering information scheme (continued)**

Example:	STM660	0	F	Q	2	4	DM	6	F
Package									
DM: TDFN12									
Temperature range									
6: -40 °C to +85 °C									

Shipping method

F: ECOPACK® package, tape and reel

1. Other options are offered. Minimum order quantities may apply. Please contact local ST sales office for availability.

Part numbering

STM6600, STM6601

Table 9. STM6601 ordering information scheme

Example:	STM660	1	G	U	2	B	DM	6	F
Device type	STM660								
Startup process									
1: PB can be released before the PS _{HOLD} confirmation									
Input and output types⁽¹⁾									
A: active high EN output, long push asserts \overline{RST} , pull-up on \overline{SR}									
B: active low \overline{EN} output, long push asserts \overline{RST} , pull-up on \overline{SR}									
C: active high EN output, long push deasserts EN, pull-up on \overline{SR}									
D: active low \overline{EN} output, long push deasserts \overline{EN} , pull-up on \overline{SR}									
G: active high EN output, long push deasserts EN, no resistor on \overline{SR}									
V_{TH+} threshold voltage⁽¹⁾									
A: 2.50 V									
M: 3.10 V									
Q: 3.30 V									
S: 3.40 V									
U: 3.50 V									
V_{HYST} voltage hysteresis⁽¹⁾									
2: 200 mV									
t_{ON_BLANK} blanking period⁽¹⁾									
B: 1.4 s (min.)									
D: 5.6 s (min.)									
Package									
DM: TDFN12									
Temperature range									
6: -40 °C to +85 °C									
Shipping method									
F: ECOPACK® package, tape and reel									

1. Other options are offered. Minimum order quantities may apply. Please contact local ST sales office for availability.

STM6600, STM6601
Product selector

10 Product selector

Table 10. STM6600 product selector

Full part number	EN or EN ⁽¹⁾	After long push ⁽²⁾	Internal resistor on SR input	Power-on lockout voltage V _{TH+} (V)	Forced power-off voltage V _{TH-} (V)	t _{ON_BLANK} (s) at startup (min.)	t _{ON_BLANK} (s) at reset (min.)	Top marking ⁽³⁾
STM6600AS24DM6F	EN	$\overline{\text{RST}}$	pull-up	3.40	3.20	5.6	5.6	pyWW AS24
STM6600BQ24DM6F	$\overline{\text{EN}}$	$\overline{\text{RST}}$	pull-up	3.30	3.10	5.6	5.6	pyWW BQ24
STM6600CS25DM6F	EN	EN	pull-up	3.40	3.20	11.2	—	pyWW CS25
STM6600DA55DM6F	$\overline{\text{EN}}$	$\overline{\text{EN}}$	pull-up	2.50	2.00	11.2	—	pyWW DA55
STM6600DQ25DM6F	$\overline{\text{EN}}$	$\overline{\text{EN}}$	pull-up	3.30	3.10	11.2	—	pyWW DQ25
STM6600DU25DM6F	$\overline{\text{EN}}$	$\overline{\text{EN}}$	pull-up	3.50	3.30	11.2	—	pyWW DU25
STM6600ES24DM6F ⁽⁴⁾	EN	$\overline{\text{RST}}$	—	3.40	3.20	5.6	5.6	pyWW ES24
STM6600FQ24DM6F ⁽⁴⁾	$\overline{\text{EN}}$	$\overline{\text{RST}}$	—	3.30	3.10	5.6	5.6	pyWW FQ24
STM6600GS22DM6F ⁽⁴⁾	EN	EN	—	3.40	3.20	1.4	—	pyWW GS22
STM6600GS25DM6F ⁽⁴⁾	EN	EN	—	3.40	3.20	11.2	—	pyWW GS25
STM6600GU22DM6F ⁽⁴⁾	EN	EN	—	3.50	3.30	1.4	—	pyWW GU22
STM6600HA55DM6F ⁽⁴⁾	$\overline{\text{EN}}$	$\overline{\text{EN}}$	—	2.50	2.00	11.2	—	pyWW HA55
STM6600HQ25DM6F ⁽⁴⁾	$\overline{\text{EN}}$	$\overline{\text{EN}}$	—	3.30	3.10	11.2	—	pyWW HQ25
STM6600HU25DM6F ⁽⁴⁾	$\overline{\text{EN}}$	$\overline{\text{EN}}$	—	3.50	3.30	11.2	—	pyWW HU25

1. EN (or $\overline{\text{EN}}$) output is push-pull. $\overline{\text{RST}}$, $\overline{\text{INT}}$, $\overline{\text{PB}_{\text{OUT}}}$ and $\overline{\text{VCC}_{\text{LO}}}$ outputs are open drain.

2. After t_{SRD} expires through long push, either device reset ($\overline{\text{RST}}$) will be activated for t_{REC} (240 ms min.) or the EN (or $\overline{\text{EN}}$) pin will be deasserted. The additional Smart Reset[™] delay time, t_{SRD} , can be adjusted by the user at 10 s/ μF (typ.) by connecting the external capacitor to the C_{SRD} pin.

3. Where "p" = assembly plant, "y" = assembly year (0 to 9) and "ww" = assembly work week (01 to 52).

4. Please contact local ST sales office for availability.

Product selector

STM6600, STM6601

Table 11. STM6601 product selector

Full part number	EN or \overline{EN} ⁽¹⁾	After long push ⁽²⁾	Internal resistor on SR input	Power-on lockout voltage V_{TH+} (V)	Forced power-off voltage V_{TH-} (V)	t_{ON_BLANK} (s) at startup (min.)	t_{ON_BLANK} (s) at reset (min.)	Top marking ⁽³⁾
STM6601AQ2BDM6F	EN	\overline{RST}	pull-up	3.30	3.10	1.4	1.4	pyww AQ2B
STM6601AU2DDM6F	EN	\overline{RST}	pull-up	3.50	3.30	5.6	5.6	pyww AU2D
STM6601BM2DDM6F	\overline{EN}	\overline{RST}	pull-up	3.10	2.90	5.6	5.6	pyww BM2D
STM6601BS2BDM6F	\overline{EN}	\overline{RST}	pull-up	3.40	3.20	1.4	1.4	pyww BS2B
STM6601CA2BDM6F	EN	EN	pull-up	2.60	2.40	1.4	—	pyww CA2B
STM6601CM2DDM6F	EN	EN	pull-up	3.10	2.90	5.6	—	pyww CM2D
STM6601CQ2BDM6F	EN	EN	pull-up	3.30	3.10	1.4	—	pyww CQ2B
STM6601CU2BDM6F	EN	EN	pull-up	3.50	3.30	1.4	—	pyww CU2B
STM6601DS2BDM6F	\overline{EN}	\overline{EN}	pull-up	3.40	3.20	1.4	—	pyww DS2B
STM6601GU2BDM6F ⁽⁴⁾	EN	EN	—	3.50	3.30	1.4	—	pyww GU2B

1. EN (or \overline{EN}) output is push-pull. \overline{RST} , \overline{INT} , $\overline{PB_{OUT}}$ and $\overline{VCC_{LO}}$ outputs are open drain.
2. After t_{SRD} expires through long push, either device reset (\overline{RST}) will be activated for t_{REC} (240 ms min.) or the EN (or \overline{EN}) pin will be deasserted. The additional Smart ResetTM delay time, t_{SRD} , can be adjusted by the user at 10 s/ μ F (typ.) by connecting the external capacitor to the C_{SRD} pin.
3. Where "p" = assembly plant, "y" = assembly year (0 to 9) and "ww" = assembly work week (01 to 52).
4. Please contact local ST sales office for availability.

11 Revision history

Table 12. Document revision history

Date	Revision	Changes
04-Mar-2009	1	Initial release.
05-Jun-2009	2	Updated text in <i>Section 2</i> , <i>Section 3</i> , <i>Figure 11</i> , <i>12</i> ; updated <i>Figure 1</i> , <i>7</i> , <i>9</i> , <i>14</i> , <i>18</i> , <i>19</i> , <i>43</i> , <i>Table 3</i> , <i>5</i> , <i>8</i> , <i>9</i> , <i>10</i> ; added <i>Figure 8</i> , <i>10</i> , <i>Table 7</i> ; reformatted document.
23-Jul-2009	3	Updated text in <i>Features</i> , <i>Table 1</i> , <i>8</i> , <i>9</i> , and <i>10</i> ; reformatted document.
22-Oct-2009	4	Updated <i>Section 2</i> , <i>Table 5</i> , <i>Table 10</i> , <i>Figure 1</i> , <i>7</i> , <i>8</i> , <i>9</i> , <i>10</i> , <i>11</i> , <i>12</i> , <i>14</i> , <i>18</i> , title of <i>Section 10</i> ; added <i>Section 5: Typical operating characteristics</i> (<i>Figure 23</i> through <i>40</i>); document status upgraded to full datasheet.
25-Jan-2010	5	Updated <i>Figure 6</i> , <i>Section 2</i> , <i>Table 5</i> ; textual update to "Smart Reset™".
13-Apr-2010	6	Updated <i>Figure 1</i> , <i>6</i> , <i>7</i> , <i>8</i> , <i>9</i> , <i>10</i> , <i>11</i> , <i>12</i> , <i>13</i> , <i>Section 2</i> , <i>Section 3</i> , <i>Table 3</i> , <i>5</i> , <i>8</i> , <i>9</i> , <i>10</i> .
07-Jun-2010	7	Reformatted <i>Figure 1</i> and <i>Figure 42</i> , corrected typo in <i>Section 3</i> , added option A to <i>Table 8</i> , updated <i>Table 10</i> and separated <i>Table 10</i> to <i>Table 10</i> and <i>Table 11</i> .
10-Sep-2010	8	Updated standby current to 0.6 μ A throughout datasheet; removed footnote 2 of <i>Figure 14</i> ; updated <i>Table 8</i> , <i>9</i> , <i>11</i> ; minor textual updates.
24-Feb-2011	9	Updated <i>Table 11</i> - removed footnote 4.
12-May-2011	10	Updated <i>Table 8</i> , <i>Table 10</i> and <i>Table 11</i> , minor text and typo modifications throughout document.
26-Jun-2012	11	Updated <i>Section 1: Description</i> , "SR - Smart Reset™ button input" in <i>Section 2: Pin descriptions</i> and "Hardware reset or power-down while system not responding" in <i>Section 3: Operation</i> , added cross-references in <i>Section 6: Maximum ratings</i> and <i>Section 7: DC and AC characteristics</i> .
13-Oct-2014	12	<i>Table 9</i> : added "A" (2.50 V) to V_{TH+} threshold voltage <i>Table 11</i> : added new full part number

STM6600, STM6601**IMPORTANT NOTICE – PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2014 STMicroelectronics – All rights reserved